

TLE207x, TLE207xA EXCALIBUR LOW-NOISE HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

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- Direct Upgrades to TL05x, TL07x, and TL08x BiFET Operational Amplifiers
- Greater Than 2× Bandwidth (10 MHz) and 3× Slew Rate (45 V/μs) Than TL07x
- Ensured Maximum Noise Floor 17 nV/√Hz
- On-Chip Offset Voltage Trimming for Improved DC Performance
- Wider Supply Rails Increase Dynamic Signal Range to ±19 V

description

The TLE207x series of JFET-input operational amplifiers more than double the bandwidth and triple the slew rate of the TL07x and TL08x families of BiFET operational amplifiers. Texas Instruments Excalibur process yields a typical noise floor of 11.6 nV/√Hz, 17-nV/√Hz ensured maximum, offering immediate improvement in noise-sensitive circuits designed using the TL07x. The TLE207x also has wider supply voltage rails, increasing the dynamic signal range for BiFET circuits to ±19 V. On-chip zener trimming of offset voltage yields precision grades for greater accuracy in dc-coupled applications. The TLE207x are pin-compatible with lower performance BiFET operational amplifiers for ease in improving performance in existing designs.

BiFET operational amplifiers offer the inherently higher input impedance of the JFET-input transistors, without sacrificing the output drive associated with bipolar amplifiers. This makes them better suited for interfacing with high-impedance sensors or very low-level ac signals. They also feature inherently better ac response than bipolar or CMOS devices having comparable power consumption.

The TLE207x family of BiFET amplifiers are Texas Instruments highest performance BiFETs, with tighter input offset voltage and ensured maximum noise specifications. Designers requiring less stringent specifications but seeking the improved ac characteristics of the TLE207x should consider the TLE208x operational amplifier family.

Because BiFET operational amplifiers are designed for use with dual power supplies, care must be taken to observe common-mode input voltage limits and output swing when operating from a single supply. DC biasing of the input signal is required and loads should be terminated to a virtual ground node at mid-supply. Texas Instruments TLE2426 integrated virtual ground generator is useful when operating BiFET amplifiers from single supplies.

The TLE207x are fully specified at ±15 V and ±5 V. For operation in low-voltage and/or single-supply systems, Texas Instruments LinCMOS families of operational amplifiers (TLC- and TLV-prefix) are recommended. When moving from BiFET to CMOS amplifiers, particular attention should be paid to slew rate and bandwidth requirements and output loading.



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TLE2071 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	CERAMIC FLAT PACK (U)
0°C to 70°C	2 mV 4 mV	TLE2071ACD TLE2071CD	—	—	TLE2071ACP TLE2071CP	—
–40°C to 85°C	2 mV 4 mV	TLE2071AID TLE2071ID	—	—	TLE2071AIP TLE2071IP	—
–55°C to 125°C	2 mV 4 mV	— —	TLE2071AMFK TLE2071MFK	TLE2071AMJG TLE2071MJG	— —	TLE2071AMU TLE2071MU

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2071ACDR).

TLE2072 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	CERAMIC FLAT PACK (U)
0°C to 70°C	3.5 mV 6 mV	TLE2072ACD TLE2072CD	—	—	TLE2072ACP TLE2072CP	—
–40°C to 85°C	3.5 mV 6 mV	TLE2072AID TLE2072ID	—	—	TLE2072AIP TLE2072IP	—
–55°C to 125°C	3.5 mV 6 mV	—	TLE2072AMFK TLE2072MFK	TLE2072AMJG TLE2072MJG	—	TLE2072AMU TLE2072MU

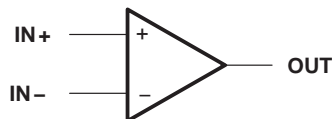
† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2072ACDR).

TLE2074 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	CERAMIC FLAT PACK (W)
0°C to 70°C	3 mV 5 mV	TLE2074ACDW TLE2074CDW	—	—	TLE2074ACN TLE2074CN	—
–40°C to 85°C	3 mV 5 mV	TLE2074AIDW TLE2074IDW	—	—	TLE2074AIN TLE2074IN	—
–55°C to 125°C	3 mV 5 mV	—	TLE2074AMFK TLE2074MFK	TLE2074AMJ TLE2074MJ	—	TLE2074AMW TLE2074MW

† The DW packages are available taped and reeled. Add R suffix to device type (e.g., TLE2074ACDWR).

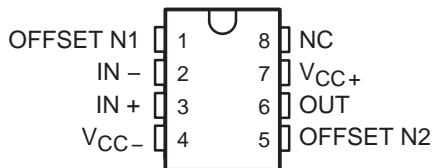
symbol



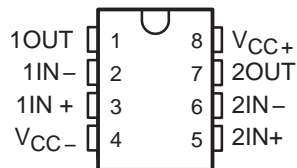
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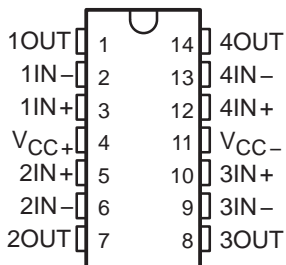
**TLE2071 AND TLE2071A
D, JG, OR P PACKAGE
(TOP VIEW)**



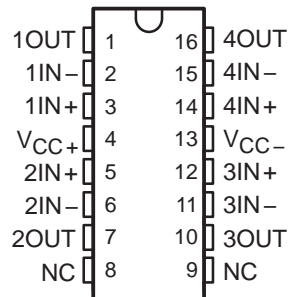
**TLE2072 AND TLE2072A
D, JG, OR P PACKAGE
(TOP VIEW)**



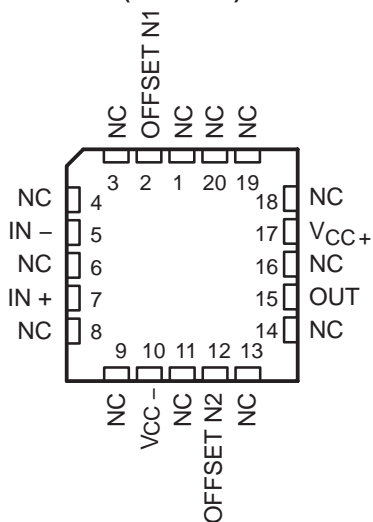
**TLE2074 AND TLE2074A
J, N, OR W PACKAGE
(TOP VIEW)**



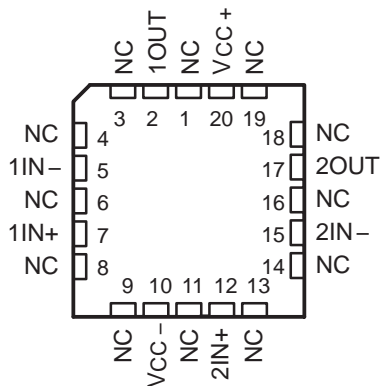
**TLE2074 AND TLE2074A
DW PACKAGE
(TOP VIEW)**



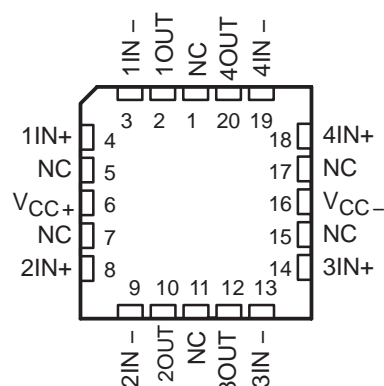
**TLE2071M AND TLE2071AM
FK PACKAGE
(TOP VIEW)**



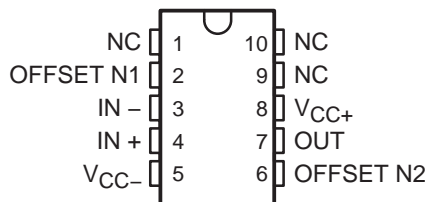
**TLE2072M AND TLE2072AM
FK PACKAGE
(TOP VIEW)**



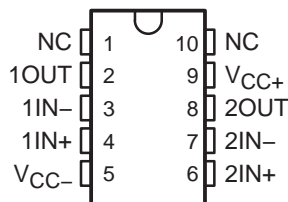
**TLE2074M AND TLE2074AM
FK PACKAGE
(TOP VIEW)**



**TLE2071 AND TLE2071A
U PACKAGE
(TOP VIEW)**



**TLE2072 AND TLE2072A
U PACKAGE
(TOP VIEW)**

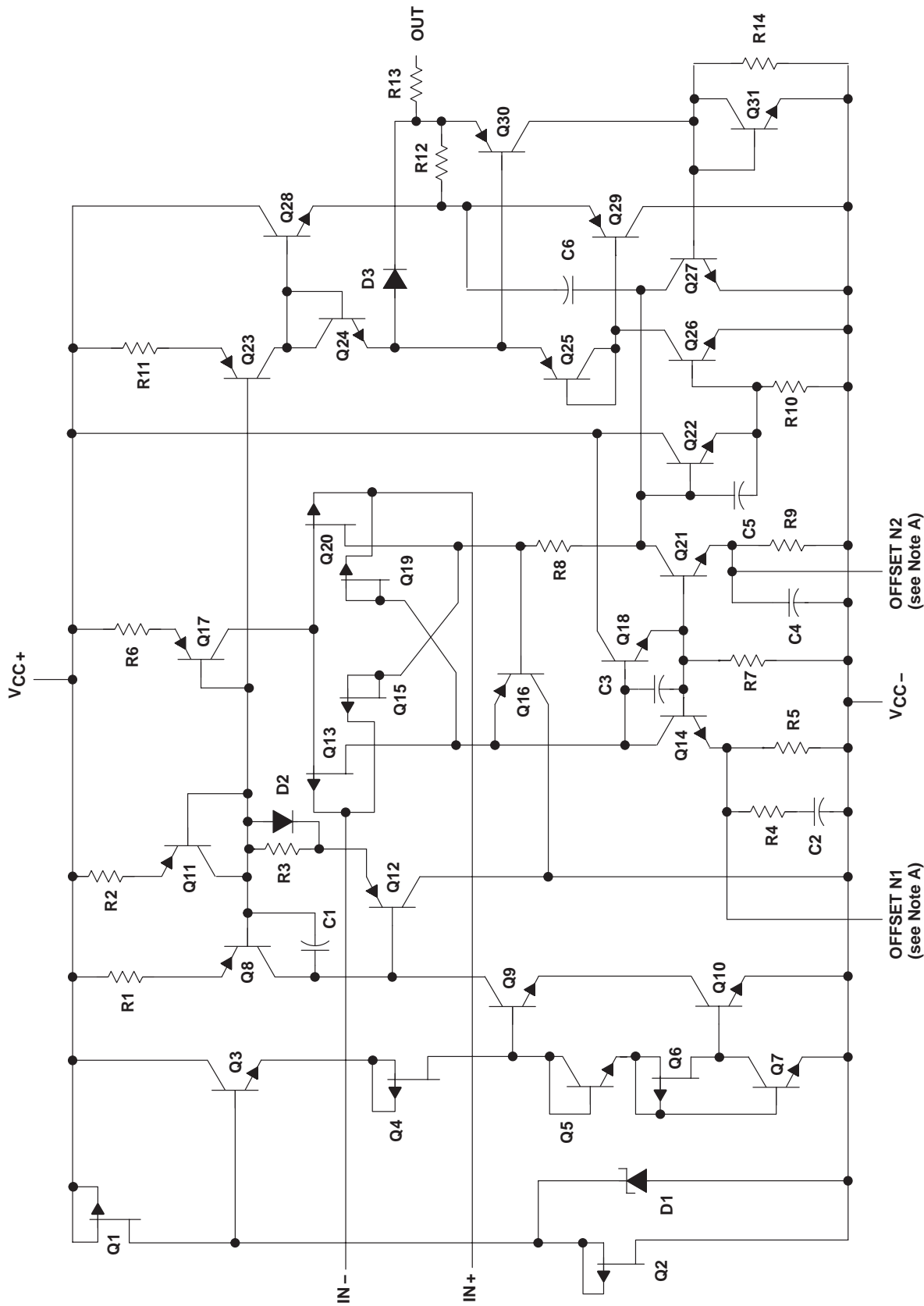


NC – No internal connection

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equivalent schematic



NOTES: A. OFFSET N1 AND OFFSET N2 are only available on the TLE2071x devices.

equivalent schematic (continued)

ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	TLE2071	TLE2072	TLE2074
Transistors	33	57	114
Resistors	25	37	74
Diodes	8	5	10
Capacitors	6	11	22

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC+} (see Note 1)	19 V
Supply voltage, V_{CC-} (see Note 1)	-19 V
Differential input voltage range, V_{ID} (see Note 2)	V_{CC+} to V_{CC-}
Input voltage range, V_I (any input)	V_{CC+} to V_{CC-}
Input current, I_I (each input)	± 1 mA
Output current, I_O (each output)	± 80 mA
Total current into V_{CC+}	160 mA
Total current out of V_{CC-}	160 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Package thermal impedance, θ_{JA} (see Notes 4 and 5):	
D package	97.1°C/W
DW package	57.3°C/W
N package	79.7°C/W
P package	84.6°C/W
Package thermal impedance, θ_{JC} (see Notes 4 and 5):	
FK package	5.6°C/W
J package	15.1°C/W
JG package	14.5°C/W
U package	14.7°C/W
W package	10°C/W
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	-40°C to 85°C
M suffix	-55°C to 125°C
Storage temperature range	-65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J, JG, U, or W package	300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at the noninverting input with respect to the inverting input.
 3. The output may be shorted to either supply. Temperatures and/or supply voltages must be limited to ensure that the maximum dissipation rate is not exceeded.
 4. Maximum power dissipation is a function of $T_J(\text{max})$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 5. The package thermal impedance is calculated in accordance with JEDEC 51-7 (plastic) or MIL-STD-883 Method 1012 (ceramic).

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{CC\pm}$		± 2.25	± 19	± 2.25	± 19	± 2.25	± 19	V
Common-mode input voltage, V_{IC}	$V_{CC\pm} = \pm 5$ V	-0.9	5	-0.8	5	-0.8	5	V
	$V_{CC\pm} = \pm 15$ V	-10.9	15	-10.8	15	-10.8	15	
Operating free-air temperature, T_A		0	70	-40	85	-55	125	°C



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TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071C			TLE2071AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	0.34	4		0.3	2	mV		
		Full range			6		4			
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	5	100		5	100	pA		
		Full range			1.4		1.4	nA		
I_{IB} Input bias current		25°C	15	175		15	175	pA		
		Full range			5		5	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.9			5 to -0.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.7			3.7				
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.4			3.4				
$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3				
	Full range	1.5			1.5					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.5	-4.2		-3.5	-4.2	V		
		Full range	-3.4			-3.4				
	$I_O = 2\ \text{mA}$	25°C	-3.7	-4.1		-3.7	-4.1			
		Full range	-3.6			-3.6				
$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4				
	Full range	-1.5			-1.5					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB	
			Full range	79			79			
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100		
			Full range	89			89			
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11			11			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	70	89		70	89	dB		
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is 0°C to 70°C.



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TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071C			TLE2071AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range				2.2			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
			$V_{ID} = -1\text{ V}$			45			

† Full range is 0°C to 70°C.

TLE2071C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2071C			TLE2071AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+ Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			V/ μ s
		Full range	23			23			
SR- Negative slew rate		25°C	38			38			V/ μ s
		Full range	23			23			
t_s Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.25		0.25		μ s	
			To 1 mV	0.4		0.4			
V_n Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz	28	55	28	55	nV/ $\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17	11.6	17		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C	f = 10 Hz to 10 kHz	6		6		μ V	
			f = 0.1 Hz to 10 Hz	0.6		0.6			
I_n Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8		fA/ $\sqrt{\text{Hz}}$		
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	$A_{VD} = 10$, $R_L = 2\text{ k}\Omega$,	25°C	0.013%		0.013%			
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$,	$R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4		9.4		MHz	
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $R_L = 2\text{ k}\Omega$,	$A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8		2.8		MHz	
ϕ_m Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$,	$R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°		56°			

† Full range is 0°C to 70°C.



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TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071C			TLE2071AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0,$ $R_S = 50\ \Omega$ $V_O = 0,$	25°C	0.49	4		0.47	2	mV		
		Full range			6		4			
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0,$ $V_O = 0,$ See Figure 4	25°C	6	100		6	100	pA		
		Full range		1.4		1.4		nA		
I_{IB} Input bias current		25°C	20	175		20	175	pA		
		Full range		5		5		nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.9		15 to -10.9					
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V		
		Full range	13.7		13.7					
	$I_O = -2\ \text{mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.4		13.4					
	$I_O = -20\ \text{mA}$	25°C	11.5	12.3		11.5	12.3			
		Full range	11.5		11.5					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range	-13.7		-13.7					
	$I_O = 2\ \text{mA}$	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.4		-13.4					
	$I_O = 20\ \text{mA}$	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.5		-11.5					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	96		80	96	dB	
			Full range	79		79				
		$R_L = 2\ \text{k}\Omega$	25°C	90	109		90	109		
			Full range	89		89				
		$R_L = 10\ \text{k}\Omega$	25°C	95	118		95	118		
			Full range	94		94				
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	7.5			7.5			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	80	98		80	98	dB		
		Full range	79		79					
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	80		81					

† Full range is 0°C to 70°C.



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TLE2071C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071C			TLE2071AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range	2.2			2.2			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1$ V	-30	-45	-30	-45	mA	
			$V_{ID} = -1$ V	30	48	30	48		

† Full range is 0°C to 70°C.

TLE2071C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A †	TLE2071C			TLE2071AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+ Positive slew rate	$V_{O(PP)} = 10$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 100$ pF, See Figure 1	25°C	30	40		30	40	V/ μ s	
		Full range	27			27			
SR- Negative slew rate		25°C	30	45		30	45	V/ μ s	
		Full range	27			27			
t_s Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1$ k Ω , $C_L = 100$ pF	25°C	To 10 mV			0.4			μ s
			To 1 mV			1.5			
V_n Equivalent input noise voltage	$R_S = 20$ Ω , See Figure 3	25°C	f = 10 Hz	28	55	28	55	nV/ $\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17	11.6	17		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C	f = 10 Hz to 10 kHz			6			μ V
			f = 0.1 Hz to 10 Hz			0.6			
I_n Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 20$ V, $A_{VD} = 10$, f = 1 kHz, $R_L = 2$ k Ω , $R_S = 25$ Ω	25°C	0.008%			0.008%			
B_1 Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C	8	10		8	10	MHz	
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 20$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 25$ pF	25°C	478	637		478	637	kHz	
ϕ_m Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C	57°			57°			

† Full range is 0°C to 70°C.



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TLE20711 electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE20711			TLE2071AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0,$ $R_S = 50\ \Omega,$ $V_O = 0,$	25°C	0.34	4		0.3	2	mV		
		Full range			7.6		5.6			
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0,$ $V_O = 0,$ See Figure 4	25°C	5	100		5	100	pA		
		Full range			5		5	nA		
I_{IB} Input bias current		25°C	15	175		15	175	pA		
		Full range			10		10	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.8			5 to -0.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.7			3.7				
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.4			3.4				
$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3				
	Full range	1.5			1.5					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V		
		Full range	-3.7			-3.7				
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.4			-3.4				
$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4				
	Full range	-1.5			-1.5					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB	
			Full range	79			79			
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100		
			Full range	89			89			
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11			11			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	70	89		70	89	dB		
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is -40°C to 85°C .



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TLE2071I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071I			TLE2071AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range	2.2			2.2			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
			$V_{ID} = -1\text{ V}$			45			

† Full range is -40°C to 85°C .

TLE2071I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2071I			TLE2071AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+ Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			V/ μs	
		Full range	22			22				
SR- Negative slew rate		25°C	38			38			V/ μs	
		Full range	22			22				
t_s Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.25			0.25			μs
			To 1 mV	0.4			0.4			
V_n Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz	28	55	28	55	nV/ $\sqrt{\text{Hz}}$		
			f = 10 kHz	11.6	17	11.6	17			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C	f = 10 Hz to 10 kHz	6			6			μV
			f = 0.1 Hz to 10 Hz	0.6			0.6			
I_n Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$	
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, $A_{VD} = 10$, f = 1 kHz, $R_L = 2\text{ k}\Omega$, $R_S = 25\ \Omega$	25°C	0.013%			0.013%				
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2	25°C	9.4			9.4			MHz	
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz	
ϕ_m Phase margin at unity gain	$V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2	25°C	56°			56°				

† Full range is -40°C to 85°C .



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TLE20711 electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE20711			TLE2071AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0,$ $R_S = 50 \Omega,$ $V_O = 0,$	25°C	0.49	4		0.47	2	mV		
		Full range			7.6		5.6			
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0,$ $V_O = 0,$ See Figure 4	25°C	6	100		6	100	pA		
		Full range			5		5	nA		
I_{IB} Input bias current		25°C	20	175		20	175	pA		
		Full range			10		10	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.8			15 to -10.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V		
		Full range	13.7			13.7				
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.4			13.4				
$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3				
	Full range	11.5			11.5					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range	-13.7			-13.7				
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.4			-13.4				
$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4				
	Full range	-11.5			-11.5					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96		80	96	dB	
			Full range	79			79			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109		90	109		
			Full range	89			89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118		95	118		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	7.5			7.5			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50 \Omega$	25°C	80	98		80	98	dB		
		Full range	79			79				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V},$ $V_O = 0,$ $R_S = 50 \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is -40°C to 85°C .



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TLE2071I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071I			TLE2071AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range	2.2			2.2			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$	-30	-45	-30	-45	mA	
			$V_{ID} = -1\text{ V}$	30	48	30	48		

† Full range is -40°C to 85°C .

TLE2071I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2071I			TLE2071AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+ Positive slew rate	$V_{O(PP)} = \pm 10\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	30	40	30	40	V/ μs		
		Full range	24			24			
SR- Negative slew rate		25°C	30	45	30	45	V/ μs		
		Full range	24			24			
t_s Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.4		0.4		μs	
			To 1 mV	1.5		1.5			
V_n Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz	28	55	28	55	nV/ $\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17	11.6	17		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C	f = 10 Hz to 10 kHz	6		6		μV	
			f = 0.1 Hz to 10 Hz	0.6		0.6			
I_n Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8		fA/ $\sqrt{\text{Hz}}$		
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	$A_{VD} = 10$, $R_L = 2\text{ k}\Omega$, 25°C	0.008%		0.008%				
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	8	10	8	10	MHz		
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	478	637	478	637	kHz		
ϕ_m Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	57°		57°				

† Full range is -40°C to 85°C .



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TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071M			TLE2071AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0,$ $R_S = 50\ \Omega,$ $V_O = 0,$	25°C	0.34	4		0.3	2	mV		
		Full range			9.2		7.2			
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29‡		3.2	29‡	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0,$ $V_O = 0,$ See Figure 4	25°C	5	100		5	100	pA		
		Full range		20		20		nA		
I_{IB} Input bias current		25°C	15	175		15	175	pA		
		Full range		60		60		nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.8		5 to -0.8					
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.6		3.6					
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.3		3.3					
	$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3			
		Full range	1.4		1.4					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V		
		Full range	-3.6		-3.6					
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.3		-3.3					
	$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.4		-1.4					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB	
			Full range	78		78				
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100		
			Full range	88		88				
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106		
			Full range	93		93				
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11			11			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	70	89		70	89	dB		
		Full range	68		68					
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	80		80					

† Full range is -55°C to 125°C .

‡ *On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.



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TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071M			TLE2071AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range				2.2			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
			$V_{ID} = -1\text{ V}$			45			

† Full range is -55°C to 125°C .

TLE2071M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2071M			TLE2071AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+ Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			$\text{V}/\mu\text{s}$	
		Full range	20‡			20‡				
SR- Negative slew rate		25°C	38			38			$\text{V}/\mu\text{s}$	
		Full range	20‡			20‡				
t_s Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV			0.25			μs	
			To 1 mV			0.4				
V_n Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	$f = 10\text{ Hz}$			28			$\text{nV}/\sqrt{\text{Hz}}$	
			$f = 10\text{ kHz}$			11.6				
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C	$f = 10\text{ Hz to } 10\text{ kHz}$			6			μV	
			$f = 0.1\text{ Hz to } 10\text{ Hz}$			0.6				
I_n Equivalent input noise current	$V_{IC} = 0$, $f = 10\text{ kHz}$	25°C	2.8			2.8			$\text{fA}/\sqrt{\text{Hz}}$	
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, $f = 1\text{ kHz}$, $R_S = 25\ \Omega$	$A_{VD} = 10$, $R_L = 2\text{ k}\Omega$	25°C	0.013%			0.013%			
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$	$R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4			9.4			MHz
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $R_L = 2\text{ k}\Omega$	$A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz
ϕ_m Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$	$R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°			56°			

† Full range is -55°C to 125°C .

‡ *On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.



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TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071M			TLE2071AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	0.49	4		0.47	2	mV	
		Full range			9.2		7.2		
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29*		3.2	29*	$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	6	100		6	100	pA	
		Full range			20		20	nA	
I_{IB} Input bias current		25°C	20	175		20	175	pA	
		Full range			60		60	nA	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V	
		Full range	15 to -10.9			15 to -10.9			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V	
		Full range	13.6			13.6			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.3			13.3			
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
		Full range	11.4			11.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V	
		Full range	-13.6			-13.6			
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14		
		Full range	-13.3			-13.3			
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4		
		Full range	-11.4			-11.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96		80	96	dB
			Full range	78			78		
		$R_L = 2 \text{ k}\Omega$	25°C	90	109		90	109	
			Full range	88			88		
		$R_L = 10 \text{ k}\Omega$	25°C	95	118		95	118	
			Full range	93			93		
r_i Input resistance	$V_{IC} = 0$	25°C	10 ¹²			10 ¹²		Ω	
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	7.5			7.5		pF
		Differential	25°C	2.5			2.5		
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80		Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98	dB	
		Full range	78			78			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99	dB	
		Full range	80			80			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .



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TLE2071M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2071M			TLE2071AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range	2.2			2.2			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1$ V	-30	-45	-30	-45	mA	
			$V_{ID} = -1$ V	30	48	30	48		

† Full range is -55°C to 125°C .

TLE2071M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A †	TLE2071M			TLE2071AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+ Positive slew rate	$V_{O(PP)} = 10$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 100$ pF, See Figure 1	25°C	30	40	30	40	V/ μ s		
		Full range	22			22			
SR- Negative slew rate		25°C	30	45	30	45	V/ μ s		
		Full range	22			22			
t_s Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1$ k Ω , $C_L = 100$ pF	25°C	To 10 mV	0.4		0.4		μ s	
			To 1 mV	1.5		1.5			
V_n Equivalent input noise voltage	$R_S = 20$ Ω , See Figure 3	25°C	f = 10 Hz	28	55*	28	55*	nV/ $\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17*	11.6	17*		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C	f = 10 Hz to 10 kHz	6		6		μ V	
			f = 0.1 Hz to 10 Hz	0.6		0.6			
I_n Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8		fA/ $\sqrt{\text{Hz}}$		
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 20$ V, $A_{VD} = 10$, f = 1 kHz, $R_S = 25$ Ω	25°C	0.008%		0.008%				
B_1 Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C	8*	10	8*	10	MHz		
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 20$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 25$ pF	25°C	478*	637	478*	637	kHz		
ϕ_m Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C	57°		57°				

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .



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TLE2071Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS			TLE2071Y			UNIT
					MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$,	$V_O = 0$,	$R_S = 50\ \Omega$	0.49	4		mV
I_{IO}	Input offset current	$V_{IC} = 0$,	$V_O = 0$,	See Figure 4	6	100		pA
I_{IB}	Input bias current				20	175		pA
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$			15 to -11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$			13.8	14.1		V
		$I_O = -2\ \text{mA}$			13.5	13.9		
		$I_O = -20\ \text{mA}$			11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$			-13.8	-14.2		V
		$I_O = 2\ \text{mA}$			-13.5	-14		
		$I_O = 20\ \text{mA}$			-11.5	-12.4		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$		80	96		dB
			$R_L = 2\ \text{k}\Omega$		90	109		
			$R_L = 10\ \text{k}\Omega$		95	118		
r_i	Input resistance	$V_{IC} = 0$			10^{12}			Ω
c_i	Input capacitance	$V_O = 0$, See Figure 5	Common mode		7.5			pF
			Differential		2.5			
z_o	Open-loop output impedance	$f = 1\ \text{MHz}$			80			Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$,	$V_O = 0$,		80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}$,		$V_O = 0$,	82	99		dB
I_{CC}	Supply current	$V_O = 0$,	No load		1.35	1.7	2.2	mA
I_{OS}	Short-circuit output current	$V_O = 0$		$V_{ID} = 1\ \text{V}$		-30	-45	mA
				$V_{ID} = -1\ \text{V}$		30	48	

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TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072C			TLE2072AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	0.9	6		0.65	3.5	mV		
		Full range			7.8		5.3			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.3	25		2.3	25	$\mu V/^\circ C$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	5	100		5	100	pA		
		Full range			1.4		1.4	nA		
I_{IB} Input bias current		25°C	15	175		15	175	pA		
		Full range			5		5	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.9			5 to -0.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.7			3.7				
	$I_O = -2 \text{ mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.4			3.4				
	$I_O = -20 \text{ mA}$	25°C	1.5	2.3		1.5	2.3			
		Full range	1.5			1.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-3.8	-4.2		-3.8	-4.2	V		
		Full range	-3.7			-3.7				
	$I_O = 2 \text{ mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.4			-3.4				
	$I_O = 20 \text{ mA}$	25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.5			-1.5				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3 \text{ V}$	$R_L = 600 \Omega$	25°C	80	91		80	91	dB	
			Full range	79			79			
		$R_L = 2 \text{ k}\Omega$	25°C	90	100		90	100		
			Full range	89			89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	106		95	106		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	11			11			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	70	89		70	89	dB		
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is 0°C to 70°C.



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TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)
(continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2072C			TLE2072AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	2.9	3.9	2.7	2.9	3.9	mA
			Full range	3.9			3.9			
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
				$V_{ID} = -1\text{ V}$			45			

TLE2072C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2072C			TLE2072AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	35			35			V/ μ s
			Full range	22			22			
SR-	Negative slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	38			38			V/ μ s
			Full range	22			22			
t_s	Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV			0.25			μ s
				To 1 mV			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz			28			nV/ $\sqrt{\text{Hz}}$
				f = 10 kHz			11.6			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz to 10 kHz			6			μ V
				f = 0.1 Hz to 10 Hz			0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	25°C	0.013%			0.013%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4			9.4			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°			56°			

† Full range is 0°C to 70°C.

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TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072C			TLE2072AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	1.1	6		0.7	3.5	mV	
		Full range			7.8		5.3		
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25	$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	6	100		6	100	pA	
		Full range			1.4		1.4	nA	
I_{IB} Input bias current		25°C	20	175		20	175	pA	
		Full range			5		5	nA	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V	
		Full range	15 to -10.9			15 to -10.9			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V	
		Full range	13.6			13.6			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.4			13.4			
$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3			
	Full range	11.5			11.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V	
		Full range	-13.7			-13.7			
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14		
		Full range	-13.4			-13.4			
$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4			
	Full range	-11.5			-11.5				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96		80	96	dB
			Full range	79			79		
		$R_L = 2 \text{ k}\Omega$	25°C	90	109		90	109	
			Full range	89			89		
		$R_L = 10 \text{ k}\Omega$	25°C	95	118		95	118	
			Full range	94			94		
r_i Input resistance	$V_{IC} = 0$	25°C	10 ¹²			10 ¹²		Ω	
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	7.5			7.5		pF
		Differential	25°C	2.5			2.5		
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80		Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98	dB	
		Full range	79			79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99	dB	
		Full range	81			81			

† Full range is 0°C to 70°C.



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TLE2072C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2072C			TLE2072AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	3.1	3.9	2.7	3.1	3.9	mA
			Full range	3.9			3.9			
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$	-30	-45	-30	-45	mA	
				$V_{ID} = -1\text{ V}$	30	48	30	48		

TLE2072C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2072C			TLE2072AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)} = 10\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	28	40	28	40	$V/\mu\text{s}$	
			Full range	25			25		
SR-	Negative slew rate	$V_{O(PP)} = 10\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	30	45	30	45	$V/\mu\text{s}$	
			Full range	25			25		
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.4		0.4		μs
				To 1 mV	1.5		1.5		
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz	28	55	28	55	$nV/\sqrt{\text{Hz}}$
				f = 10 kHz	11.6	17	11.6	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz to 10 kHz	6		6		μV
				f = 0.1 Hz to 10 Hz	0.6		0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8		$fA/\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$, $A_{VD} = 10$, $R_L = 2\text{ k}\Omega$	25°C	0.008%		0.008%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	8	10	8	10	MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	478	637	478	637	kHz	
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	57°		57°			

† Full range is 0°C to 70°C.



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TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072I			TLE2072AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega,$	25°C	0.9	6		0.65	3.5	mV	
		Full range			9.1		6.4		
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25	$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	5	100		5	100	pA	
		Full range			5		5	nA	
I_{IB} Input bias current		25°C	15	175		15	175	pA	
		Full range			10		10	nA	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V	
		Full range	5 to -0.8			5 to -0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V	
		Full range	3.7			3.7			
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.4			3.4			
	$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.5			1.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V	
		Full range	-3.7			-3.7			
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.4			-3.4			
	$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.5			-1.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB
			Full range	79			79		
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100	
			Full range	89			89		
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106	
			Full range	94			94		
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}		Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11			11		pF
		Differential	25°C	2.5			2.5		
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80		Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0,$ $R_S = 50\ \Omega$	25°C	70	89		70	89	dB	
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V}, V_O = 0,$ $R_S = 50\ \Omega$	25°C	82	99		82	99	dB	
		Full range	80			80			

† Full range is -40°C to 85°C .



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TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2072I			TLE2072AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	2.9	3.9	2.7	2.9	3.9	mA
			Full range	3.9			3.9			
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
				$V_{ID} = -1\text{ V}$			45			

TLE2072I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2072I			TLE2072AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	35			35			V/ μ s
			Full range	20			20			
SR-	Negative slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	38			38			V/ μ s
			Full range	20			20			
t_s	Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV			0.25			μ s
				To 1 mV			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz			28			nV/ $\sqrt{\text{Hz}}$
				f = 10 kHz			11.6			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz to 10 kHz			6			μ V
				f = 0.1 Hz to 10 Hz			0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	25°C	0.013%			0.013%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4			9.4			MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°			56°			

† Full range is 40°C to 85°C.



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TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072I			TLE2072AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	1.1	6		0.7	3.5	mV		
		Full range			9.1		6.4			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	6	100		6	100	pA		
		Full range			5		5	nA		
I_{IB} Input bias current		25°C	20	175		20	175	pA		
		Full range			10		10	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.8			15 to -10.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V		
		Full range			13.7		13.7			
	$I_O = -2\ \text{mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range			13.4		13.4			
	$I_O = -20\ \text{mA}$	25°C	11.5	12.3		11.5	12.3			
		Full range			11.5		11.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range			-13.7		-13.7			
	$I_O = 2\ \text{mA}$	25°C	-13.5	-14		-13.5	-14			
		Full range			-13.4		-13.4			
	$I_O = 20\ \text{mA}$	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range			-11.5		-11.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	96		80	96	dB	
			Full range			79		79		
		$R_L = 2\ \text{k}\Omega$	25°C	90	109		90	109		
			Full range			89		89		
		$R_L = 10\ \text{k}\Omega$	25°C	95	118		95	118		
			Full range			94		94		
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	7.5			7.5			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	80	98		80	98	dB		
		Full range			79		79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range			80		80			

† Full range is -40°C to 85°C .



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TLE2072I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)
(continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2072I			TLE2072AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	3.1	3.9	2.7	3.1	3.9	mA
			Full range	3.9			3.9			
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$	-30	-45	-30	-45	mA	
				$V_{ID} = -1\text{ V}$	30	48	30	48		

TLE2072I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2072I			TLE2072AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)} = \pm 10\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	28	40	28	40	$V/\mu\text{s}$	
			Full range	22			22		
SR-	Negative slew rate		25°C	30	45	30	45	$V/\mu\text{s}$	
			Full range	22			22		
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.4		0.4		μs
				To 1 mV	1.5		1.5		
V_n	Equivalent input noise voltage		25°C	f = 10 Hz	28	55	28	55	$nV/\sqrt{\text{Hz}}$
				f = 10 kHz	11.6	17	11.6	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 0 Hz to 10 kHz	6		6		μV
				f = 0.1 Hz to 10 Hz	0.6		0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8		$fA/\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	25°C	0.008%		0.008%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	8	10	8	10	MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	478	637	478	637	kHz	
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	57°		57°			

† Full range is -40°C to 85°C.

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TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072M			TLE2072AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0,$ $R_S = 50\ \Omega,$ $V_O = 0,$	25°C	0.9	6		0.65	3.5	mV		
		Full range			10.5		8			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.3	25*		2.3	25*	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0,$ $V_O = 0,$ See Figure 4	25°C	5	100		5	100	pA		
		Full range			20		20	nA		
I_{IB} Input bias current		25°C	15	175		15	175	pA		
		Full range			60		60	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.8			5 to -0.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.6			3.6				
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.3			3.3				
	$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3			
		Full range	1.4			1.4				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V		
		Full range	-3.6			-3.6				
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.3			-3.3				
	$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.4			-1.4				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB	
			Full range	78			78			
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100		
			Full range	88			88			
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106		
			Full range	93			93			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11			11			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	70	89		70	89	dB		
		Full range	68			68				

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .



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TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072M			TLE2072AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\text{ V}$ to $\pm 15\text{ V}$, $V_O = 0$, $R_S = 50\ \Omega$	Full range	80			80			dB
I_{CC}	Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	2.9	3.6	2.7	2.9	3.6	mA
			Full range			3.6			3.6	
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C		120			120		dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			–35			mA
				$V_{ID} = -1\text{ V}$			45			

† Full range is -55°C to 125°C .

TLE2072M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2072M			TLE2072AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$SR+$	Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			V/ μs
			Full range	18*			18*			
$SR-$	Negative slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	38			38			V/ μs
			Full range	18*			18*			
t_s	Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	To 10 mV	0.25			0.25			μs
			To 1 mV	0.4			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	f = 10 Hz	28	55*		28	55*	nV/ $\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17*		11.6	17*		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	f = 10 Hz to 10 kHz	6			6			μV
			f = 0.1 Hz to 10 Hz	0.6			0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	25°C	0.013%			0.013%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4			9.4			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°			56°			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .



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TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072M			TLE2072AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	1.1	6		0.7	3.5	mV		
		Full range			10.5		8			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.4	25*		2.4	25*	$\mu V/^\circ C$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	6	100		6	100	pA		
		Full range			20		20	nA		
I_{IB} Input bias current		25°C	20	175		20	175	pA		
		Full range			60		60	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.8			15 to -10.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1	V		
		Full range	13.6			13.6				
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.3			13.3				
$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3				
	Full range	11.4			11.4					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range	-13.6			-13.6				
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.3			-13.3				
$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4				
	Full range	-11.4			-11.4					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96		80	96	dB	
			Full range	78			78			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109		90	109		
			Full range	89			89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118		95	118		
			Full range	93			93			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	7.5			7.5			pF
		Differential	25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98	dB		
		Full range	78			78				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.



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TLE2072M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2072M			TLE2072AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	3.1	3.6	2.7	3.1	3.6	mA
			Full range	3.6			3.6			
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$	-30	-45	-30	-45	mA	
				$V_{ID} = -1\text{ V}$	30	48	30	48		

† Full range is -55°C to 125°C .

TLE2072M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2072M			TLE2072AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)} = 10\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	28	40		28	40	$\text{V}/\mu\text{s}$
			Full range	20			20		
SR-	Negative slew rate	$V_{O(PP)} = 10\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	30	45		30	45	$\text{V}/\mu\text{s}$
			Full range	20			20		
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.4		0.4		μs
				To 1 mV	1.5		1.5		
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	$f = 10\text{ Hz}$	28	55*	28	55*	$\text{nV}/\sqrt{\text{Hz}}$
				$f = 10\text{ kHz}$	11.6	17*	11.6	17*	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	$f = 10\text{ Hz}$ to 10 kHz	6		6		μV
				$f = 0.1\text{ Hz}$ to 10 Hz	0.6		0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10\text{ kHz}$	25°C	2.8		2.8		$\text{fA}/\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $f = 1\text{ kHz}$, $R_S = 25\ \Omega$, $A_{VD} = 10$, $R_L = 2\text{ k}\Omega$	25°C	0.008%		0.008%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2	25°C	8*	10	8*	10	MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	478*	637	478*	637	kHz	
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2	25°C	57°		57°			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .



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TLE2072Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TLE2072Y			UNIT
		MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$		1.1	6	mV
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4		6	100	pA
I_{IB} Input bias current			20	175	pA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	15 to -11	15 to 11.9		V
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	13.8	14.1		V
	$I_O = -2\ \text{mA}$	13.5	13.9		
	$I_O = -20\ \text{mA}$	11.5	12.3		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	-13.8	-14.2		V
	$I_O = 2\ \text{mA}$	-13.5	-14		
	$I_O = 20\ \text{mA}$	-11.5	-12.4		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	80	96	dB
		$R_L = 2\ \text{k}\Omega$	90	109	
		$R_L = 10\ \text{k}\Omega$	95	118	
r_i Input resistance	$V_{IC} = 0$		10 ¹²		Ω
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	7.5		pF
		Differential	2.5		
z_o Open-loop output impedance	$f = 1\ \text{MHz}$		80		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $V_O = 0$, $R_S = 50\ \Omega$	80	98		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}$, $R_S = 50\ \Omega$, $V_O = 0$	82	99		dB
I_{CC} Supply current (both channels)	$V_O = 0$, No load	2.7	3.1	3.9	mA
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\ \text{V}$	-30	-45	mA
		$V_{ID} = -1\ \text{V}$	30	48	

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TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074C			TLE2074AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega$	25°C	-1.6	5		-0.5	3	mV	
		Full range			7.1		5.1		
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30		10.1	30	$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	15	100		15	100	pA	
		Full range			1400		1400		
I_{IB} Input bias current		25°C	20	175		20	175	pA	
		Full range			5000		5000		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V	
		Full range	5 to -0.9			5 to -0.9			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V	
		Full range	3.7			3.7			
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.4			3.4			
	$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.5			1.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V	
		Full range	-3.7			-3.7			
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.4			-3.4			
	$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.5			-1.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB
			Full range	79			79		
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100	
			Full range	89			89		
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106	
			Full range	94			94		
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω
c_i Input capacitance	Common mode	25°C	11			11			pF
	Differential	$V_{IC} = 0,$ See Figure 5	25°C	2.5			2.5		
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0,$ $R_S = 50\ \Omega$	25°C	70	89		70	89	dB	
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V}, V_O = 0,$ $R_S = 50\ \Omega$	25°C	82	99		82	99	dB	
		Full range	80			80			

† Full range is 0°C to 70°C.

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TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074C			TLE2074AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current (four amplifiers) $V_O = 0$, No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
		Full range	7.5			7.5			
	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	120			120			dB
I_{OS}	Short-circuit output current $V_O = 0$	$V_{ID} = 1\text{ V}$	-35			-35			mA
		$V_{ID} = -1\text{ V}$	45			45			

† Full range is 0°C to 70°C.

TLE2074C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2074C			TLE2074AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	25°C	35			35			V/ μ s
		Full range	22			22			
SR-	Negative slew rate	25°C	38			38			V/ μ s
		Full range	22			22			
t_s	Settling time	25°C	To 10 mV			0.25			μ s
			To 1 mV			0.4			
V_n	Equivalent input noise voltage	25°C	f = 10 Hz			28 55			nV/ $\sqrt{\text{Hz}}$
			f = 10 kHz			11.6 17			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	25°C	f = 10 Hz to 10 kHz			6			μ V
			f = 0.1 Hz to 10 Hz			0.6			
I_n	Equivalent input noise current	25°C	f = 10 kHz			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	25°C	0.013%			0.013%			
B_1	Unity-gain bandwidth	25°C	9.4			9.4			MHz
B_{OM}	Maximum output-swing bandwidth	25°C	2.8			2.8			MHz
ϕ_m	Phase margin at unity gain	25°C	56°			56°			

† Full range is 0°C to 70°C.



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TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074C			TLE2074AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	-1.6	5		-0.5	3	mV		
		Full range			7.1		5.1			
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30		10.1	30	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	15	100		15	100	pA		
		Full range			1400		1400			
I_{IB} Input bias current		25°C	25	175		25	175	pA		
		Full range			5000		5000			
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.9			15 to -10.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V		
		Full range	13.7			13.7				
	$I_O = -2\ \text{mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.4			13.4				
	$I_O = -20\ \text{mA}$	25°C	11.5	12.3		11.5	12.3			
		Full range	11.5			11.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range	-13.7			-13.7				
	$I_O = 2\ \text{mA}$	25°C	-13.7	-14		-13.7	-14			
		Full range	-13.6			-13.6				
	$I_O = 20\ \text{mA}$	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.5			-11.5				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	96		80	96	dB	
			Full range	79			79			
		$R_L = 2\ \text{k}\Omega$	25°C	90	109		90	109		
			Full range	89			89			
		$R_L = 10\ \text{k}\Omega$	25°C	95	118		95	118		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	Common mode	$V_{IC} = 0, \text{See Figure 5}$	25°C	7.5			7.5			pF
	Differential		25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	80	98		80	98	dB		
		Full range	79			79				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	81			81				

† Full range is 0°C to 70°C.



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TLE2074C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074C			TLE2074AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
			Full range	7.5			7.5			
	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$	-30	-45	-30	-45	mA	
				$V_{ID} = -1\text{ V}$	30	48	30	48		

† Full range is 0°C to 70°C.

TLE2074C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2074C			TLE2074AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_{O(PP)} = 10\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	25	40	25	40	V/ μ s	
			Full range	22			22		
SR-	Negative slew rate		25°C	30	45	30	45	V/ μ s	
			Full range	25			25		
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV	0.4		0.4		μ s
				To 1 mV	1.5		1.5		
V_n	Equivalent input noise voltage		25°C	f = 10 Hz	28	55	28	55	nV/ $\sqrt{\text{Hz}}$
				f = 10 kHz	11.6	17	11.6	17	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	f = 10 Hz to 10 kHz	6		6		μ V
				f = 0.1 Hz to 10 Hz	0.6		0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8		fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$, f = 1 kHz, $R_L = 2\text{ k}\Omega$, $R_S = 25\ \Omega$	25°C	0.008%		0.008%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2	25°C	8	10	8	10	MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$	25°C	478	637	478	637	kHz	
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2	25°C	57°		57°			

† Full range is 0°C to 70°C.



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TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074I			TLE2074AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega$	25°C	-1.6	5		-0.5	3	mV		
		Full range			9		7			
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30		10.1	30	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	15	100		15	100	pA		
		Full range		5			5	nA		
I_{IB} Input bias current		25°C	20	175		20	175	pA		
		Full range		10			10	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.8			5 to -0.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.7			3.7				
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.4			3.4				
$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3				
	Full range	1.5			1.5					
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V		
		Full range	-3.7			-3.7				
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.4			-3.4				
$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4				
	Full range	-1.5			-1.5					
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91		80	91	dB	
			Full range	79			79			
		$R_L = 2\ \text{k}\Omega$	25°C	90	100		90	100		
			Full range	89			89			
		$R_L = 10\ \text{k}\Omega$	25°C	95	106		95	106		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	Common mode	$V_{IC} = 0,$ See Figure 5	25°C	11			11			pF
	Differential		25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0, R_S = 50\ \Omega$	25°C	70	89		70	89	dB		
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V},$ $V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is -40°C to 85°C .

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TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074I			TLE2074AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
			Full range	7.5			7.5			
	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
				$V_{ID} = -1\text{ V}$			45			

† Full range is -40°C to 85°C .

TLE2074I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2074I			TLE2074AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_O(PP) = \pm 2.3\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	35			35			$\text{V}/\mu\text{s}$
			Full range	20			20			
SR-	Negative slew rate	$V_O(PP) = \pm 2.3\text{ V}$, $A_{VD} = -1$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 1	25°C	38			38			$\text{V}/\mu\text{s}$
			Full range	20			20			
t_s	Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	To 10 mV			0.25			μs
				To 1 mV			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	$f = 10\text{ Hz}$			28 55			$\text{nV}/\sqrt{\text{Hz}}$
				$f = 10\text{ kHz}$			11.6 17			
$V_N(PP)$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	25°C	$f = 10\text{ Hz to } 10\text{ kHz}$			6			μV
				$f = 0.1\text{ Hz to } 10\text{ Hz}$			0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10\text{ kHz}$	25°C	2.8			2.8			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 5\text{ V}$, $f = 1\text{ kHz}$, $R_S = 25\ \Omega$	25°C	0.013%			0.013%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4			9.4			MHz
B_{OM}	Maximum output-swing bandwidth	$V_O(PP) = 4\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°			56°			

† Full range is -40°C to 85°C .



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TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074I			TLE2074AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50 \Omega$	25°C	-1.6	5		-0.5	3	mV		
		Full range			9		7			
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30		10.1	30	$\mu V/^\circ C$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	15	100		15	100	pA		
		Full range		5		5		nA		
I_{IB} Input bias current		25°C	25	175		25	175	pA		
		Full range		10		10		nA		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.8			15 to -10.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1	V		
		Full range	13.7			13.7				
	$I_O = -2$ mA	25°C	13.5	13.9		13.5	13.9			
		Full range	13.4			13.4				
	$I_O = -20$ mA	25°C	11.5	12.3		11.5	12.3			
		Full range	11.5			11.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range	-13.7			-13.7				
	$I_O = 2$ mA	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.4			-13.4				
	$I_O = 20$ mA	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.5			-11.5				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V	$R_L = 600 \Omega$	25°C	80	96		80	96	dB	
			Full range	79			79			
		$R_L = 2$ k Ω	25°C	90	109		90	109		
			Full range	89			89			
		$R_L = 10$ k Ω	25°C	95	118		95	118		
			Full range	94			94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	Common mode	$V_{IC} = 0,$ See Figure 5	25°C	7.5			7.5			pF
	Differential		25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1$ MHz	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98	dB		
		Full range	79			79				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is $-40^\circ C$ to $85^\circ C$.



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TLE2074I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074I			TLE2074AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
			Full range	7.5			7.5			
	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2$ k Ω	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1$ V	-30	-45	-30	-45	mA	
				$V_{ID} = -1$ V	30	48	30	48		

† Full range is -40°C to 85°C .

TLE2074I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A †	TLE2074I			TLE2074AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_{O(PP)} = \pm 10$ V, $A_{VD} = -1$, $C_L = 100$ pF, $R_L = 2$ k Ω , See Figure 1	25°C	25	40	25	40	V/ μ s		
			Full range	19			19			
SR-	Negative slew rate	$V_{O(PP)} = \pm 10$ V, $A_{VD} = -1$, $C_L = 100$ pF, $R_L = 2$ k Ω , See Figure 1	25°C	30	45	30	45	V/ μ s		
			Full range	22			22			
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1$ k Ω , $C_L = 100$ pF	To 10 mV	0.4			0.4			μ s
			To 1 mV	1.5			1.5			
V_n	Equivalent input noise voltage	$R_S = 20$ Ω , See Figure 3	f = 10 Hz	28	55	28	55	nV/ $\sqrt{\text{Hz}}$		
			f = 10 kHz	11.6	17	11.6	17			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20$ Ω , See Figure 3	f = 10 Hz to 10 kHz	6			6			μ V
			f = 0.1 Hz to 10 Hz	0.6			0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20$ V, $A_{VD} = 10$, f = 1 kHz, $R_L = 2$ k Ω , $R_S = 25$ Ω	25°C	0.008%			0.008%			
B_1	Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C	8	10	8	10	MHz		
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 25$ pF	25°C	478	637	478	637	kHz		
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C	57°			57°			

† Full range is -40°C to 85°C .



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TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074M			TLE2074AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50\Omega$	25°C	-1.6	5		-0.5	3	mV		
		Full range			10.5		8.5			
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30‡		10.1	30‡	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	15	100		15	100	pA		
		Full range			20		20	nA		
I_{IB} Input bias current		25°C	20	175		20	175	pA		
		Full range			60		60	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9	V		
		Full range	5 to -0.8			5 to -0.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\mu\text{A}$	25°C	3.8	4.1		3.8	4.1	V		
		Full range	3.6			3.6				
	$I_O = -2\text{ mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.3			3.3				
	$I_O = -20\text{ mA}$	25°C	1.5	2.3		1.5	2.3			
		Full range	1.4			1.4				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2	V		
		Full range	-3.6			-3.6				
	$I_O = 2\text{ mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.3			-3.3				
	$I_O = 20\text{ mA}$	25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.4			-1.4				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\text{ V}$	$R_L = 600\Omega$	25°C	80	91		80	91	dB	
			Full range	78			78			
		$R_L = 2\text{ k}\Omega$	25°C	90	100		90	100		
			Full range	88			88			
		$R_L = 10\text{ k}\Omega$	25°C	95	106		95	106		
			Full range	93			93			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	Common mode	$V_{IC} = 0,$ See Figure 5	25°C	11			11			pF
	Differential		25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0, R_S = 50\Omega$	25°C	70	89		70	89	dB		
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\text{ V to } \pm 15\text{ V},$ $V_O = 0, R_S = 50\Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is -55°C to 125°C .

‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.



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TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074M			TLE2074AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
			Full range	7.5			7.5			
	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\text{ V}$			-35			mA
				$V_{ID} = -1\text{ V}$			45			

† Full range is -55°C to 125°C .

TLE2074M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLE2074M			TLE2074AM			UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX			
SR+	Positive slew rate	$V_{O(PP)} = \pm 2.3\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			$\text{V}/\mu\text{s}$	
			Full range	18‡			18‡				
SR-	Negative slew rate		25°C	38			38			$\text{V}/\mu\text{s}$	
			Full range	18‡			18‡				
t_s	Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	To 10 mV	0.25			0.25			μs	
			To 1 mV	0.4			0.4				
V_n	Equivalent input noise voltage		f = 10 Hz	28	55‡		28	55‡		$\text{nV}/\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17‡		11.6	17‡			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\ \Omega$, See Figure 3	f = 10 Hz to 10 kHz	6			6			μV	
			f = 0.1 Hz to 10 Hz	0.6			0.6				
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			$\text{fA}/\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 5\text{ V}$, f = 1 kHz, $R_S = 25\ \Omega$	$A_{VD} = 10$, $R_L = 2\text{ k}\Omega$	25°C	0.013%			0.013%			
B_1	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$	$R_L = 2\text{ k}\Omega$, See Figure 2	25°C	9.4			9.4			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 4\text{ V}$, $R_L = 2\text{ k}\Omega$	$A_{VD} = -1$, $C_L = 25\text{ pF}$	25°C	2.8			2.8			MHz
f_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$	$R_L = 2\text{ k}\Omega$, See Figure 2	25°C	56°			56°			

† Full range is -55°C to 125°C .

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TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074M			TLE2074AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega$	25°C	-1.6	5		-0.5	3	mV		
		Full range			10.5		8.5			
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30‡		10.1	30‡	$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	15	100		15	100	pA		
		Full range		20			20	nA		
I_{IB} Input bias current		25°C	25	175		25	175	pA		
		Full range		60			60	nA		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9	V		
		Full range	15 to -10.8			15 to -10.8				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	13.8	14.1		13.8	14.1	V		
		Full range	13.6			13.6				
	$I_O = -2\ \text{mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.3			13.3				
	$I_O = -20\ \text{mA}$	25°C	11.5	12.3		11.5	12.3			
		Full range	11.4			11.4				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2	V		
		Full range	-13.6			-13.6				
	$I_O = 2\ \text{mA}$	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.3			-13.3				
	$I_O = 20\ \text{mA}$	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.4			-11.4				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	96		80	96	dB	
			Full range	78			78			
		$R_L = 2\ \text{k}\Omega$	25°C	90	109		90	109		
			Full range	88			88			
		$R_L = 10\ \text{k}\Omega$	25°C	95	118		95	118		
			Full range	93			93			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω	
c_i Input capacitance	Common mode	$V_{IC} = 0,$ See Figure 5	25°C	7.5			7.5			pF
	Differential		25°C	2.5			2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0, R_S = 50\ \Omega$	25°C	80	98		80	98	dB		
		Full range	78			78				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V to } \pm 15\ \text{V},$ $V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99	dB		
		Full range	80			80				

† Full range is -55°C to 125°C .

‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.



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TLE2074M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A †	TLE2074M			TLE2074AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
			Full range	7.5			7.5			
	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2$ k Ω	25°C	120			120			dB
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1$ V	-30	-45	-30	-45	mA	
				$V_{ID} = -1$ V	30	48	30	48		

† Full range is -55°C to 125°C .

TLE2074M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A †	TLE2074M			TLE2074AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_{O(PP)} = 10$ V, $R_L = 2$ k Ω , $C_L = 100$ pF, See Figure 1	25°C	25	40		25	40	V/ μ s	
			Full range	17			17			
SR-	Negative slew rate	See Figure 1	25°C	30	45		30	45	V/ μ s	
			Full range	20			20			
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1$ k Ω , $C_L = 100$ pF	To 10 mV	0.4			0.4			μ s
			To 1 mV	1.5			1.5			
V_n	Equivalent input noise voltage	$R_S = 20$ Ω , See Figure 3	f = 10 Hz	28	55‡		28	55‡	nV/ $\sqrt{\text{Hz}}$	
			f = 10 kHz	11.6	17‡		11.6	17‡		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	See Figure 3	f = 10 Hz to 10 kHz	6			6			μ V
			f = 0.1 Hz to 10 Hz	0.6			0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8			2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20$ V, f = 1 kHz, $R_S = 25$ Ω	25°C	0.008%			0.008%			
B_1	Unity-gain bandwidth	$V_I = 10$ mV, $C_L = 25$ pF, $R_L = 2$ k Ω , See Figure 2	25°C	8‡	10		8‡	10	MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20$ V, $R_L = 2$ k Ω , $A_{VD} = -1$, $C_L = 25$ pF	25°C	478‡	637		478‡	637	kHz	
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $C_L = 25$ pF, $R_L = 2$ k Ω , See Figure 2	25°C	57°			57°			

† Full range is -55°C to 125°C .

‡ On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.



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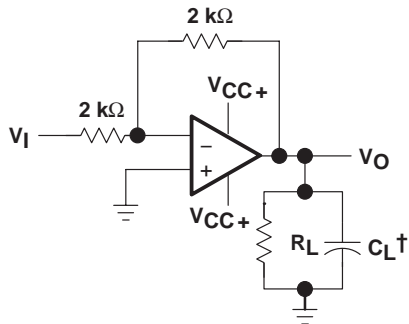
TLE2074Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TLE2074Y			UNIT
				MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$	$V_O = 0$,			5	mV
I_{IO}	Input offset current	$V_{IC} = 0$, See Figure 4	$V_O = 0$,		15	100	pA
I_{IB}	Input bias current				25	175	pA
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$		15 to -11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$		13.8	14.1		V
		$I_O = -2\ \text{mA}$		13.5	13.9		
		$I_O = -20\ \text{mA}$		11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$		-13.8	-14.2		V
		$I_O = 2\ \text{mA}$		-13.5	-14		
		$I_O = 20\ \text{mA}$		-11.5	-12.4		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	80	96		dB
			$R_L = 2\ \text{k}\Omega$	90	109		
			$R_L = 10\ \text{k}\Omega$	95	118		
r_i	Input resistance	$V_{IC} = 0$			10^{12}		Ω
c_i	Input capacitance	Common mode	$V_O = 0$, See Figure 5		7.5		pF
		Differential			2.5		
z_o	Open-loop output impedance	$f = 1\ \text{MHz}$			80		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}^{\text{min}}$, $R_S = 50\ \Omega$	$V_O = 0$,	80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}$, $V_O = 0$,	$R_S = 50\ \Omega$	82	99		dB
I_{CC}	Supply current (four amplifiers)	$V_O = 0$,	No load	5.2	6.5	7.5	mA
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1\ \text{V}$	-30	-45		mA
			$V_{ID} = -1\ \text{V}$	30	48		

TLE207x, TLE207xA EXCALIBUR LOW-NOISE HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

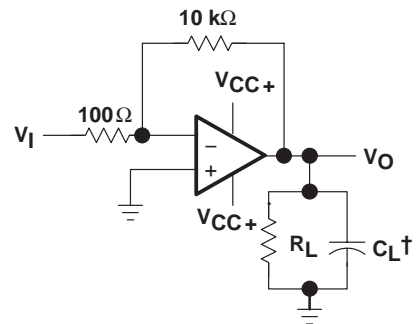
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PARAMETER MEASUREMENT INFORMATION



† Includes fixture capacitance

Figure 1. Slew-Rate Test Circuit



† Includes fixture capacitance

Figure 2. Unity-Gain Bandwidth and Phase-Margin Test Circuit

PARAMETER MEASUREMENT INFORMATION

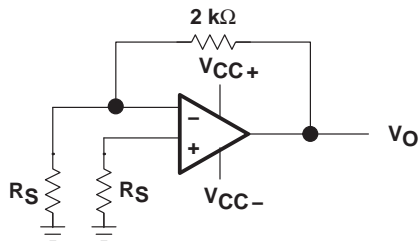


Figure 3. Noise-Voltage Test Circuit

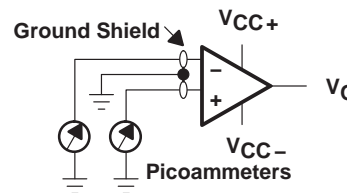


Figure 4. Input-Bias and Offset-Current Test Circuit

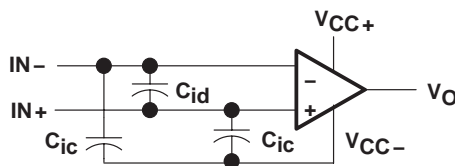


Figure 5. Internal Input Capacitance

typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoampere bias current level typical of the TLE207x and TLE207xA, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket and a second test is performed that measures both the socket leakage and the device input bias current. The two measurements are then subtracted algebraically to determine the bias current of the device.

TLE207x, TLE207xA
EXCALIBUR LOW-NOISE HIGH-SPEED
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TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	6, 7, 8
α_{VIO}	Temperature coefficient of input offset voltage	Distribution	9, 10, 11
I_{IO}	Input offset current	vs Free-air temperature	12, 13
I_{IB}	Input bias current	vs Free-air temperature vs Total supply voltage	12, 13 14
V_{ICR}	Common-mode input voltage range	vs Free-air temperature	15
V_O	Output voltage	vs Differential input voltage	16, 17
V_{OM+}	Maximum positive peak output voltage	vs Output current	18
V_{OM-}	Maximum negative peak output voltage	vs Output current	19
V_{OM}	Maximum peak output voltage	vs Free-air temperature vs Supply voltage	20, 21 22
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	23
V_O	Output voltage	vs Settling time	24
A_{VD}	Large-signal differential voltage amplification	vs Load resistance vs Free-air temperature	25 26, 27
A_{VD}	Small-signal differential voltage amplification	vs Frequency	28, 29
$CMRR$	Common-mode rejection ratio	vs Frequency vs Free-air temperature	30 31
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	32 33
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature vs Differential input voltage	34, 35, 36 37, 38, 39 40 – 45
I_{OS}	Short-circuit output current	vs Supply voltage vs Elapsed time vs Free-air temperature	46 47 48
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V_n	Equivalent Input noise voltage (spectral density)	vs Frequency	53
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	Third-octave spectral noise density	vs Frequency bands	56
$THD + N$	Total harmonic distortion plus noise	vs Frequency	57, 58
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	Gain-bandwidth product	vs Free-air temperature vs Supply voltage	60 61
	Gain margin	vs Load capacitance	62
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	Phase shift	vs Frequency	28, 29
	Noninverting large-signal pulse response	vs Time	66
	Small-signal pulse response	vs Time	67
z_o	Closed-loop output impedance	vs Frequency	68
	Crosstalk attenuation	vs Frequency	69



TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLE2071
 INPUT OFFSET VOLTAGE

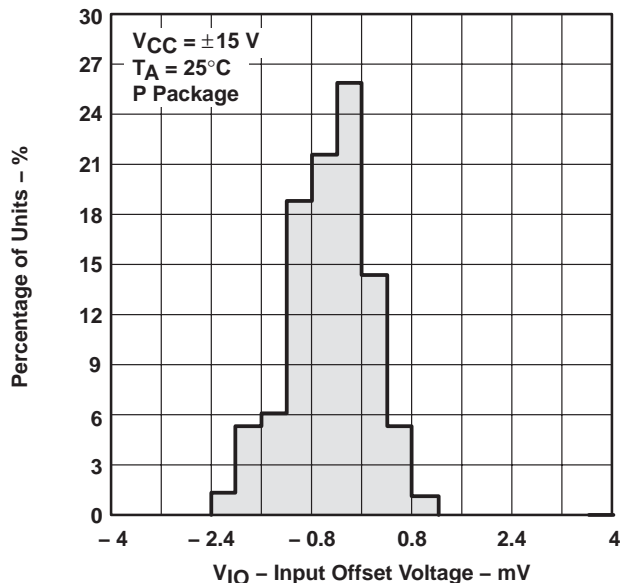


Figure 6

DISTRIBUTION OF TLE2072
 INPUT OFFSET VOLTAGE

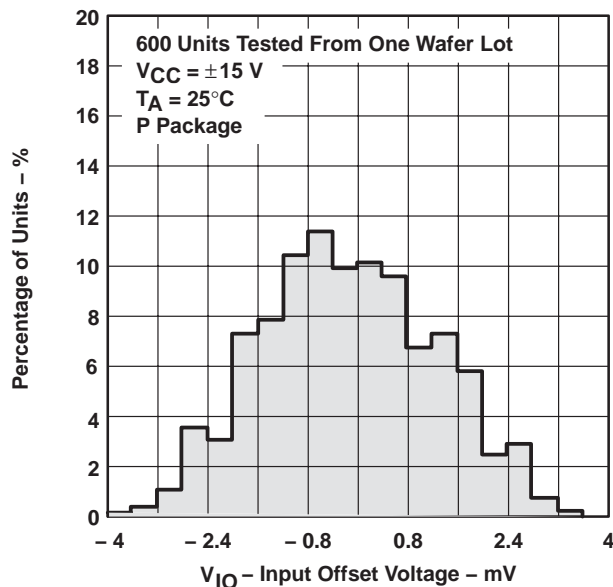


Figure 7

DISTRIBUTION OF TLE2074
 INPUT OFFSET VOLTAGE

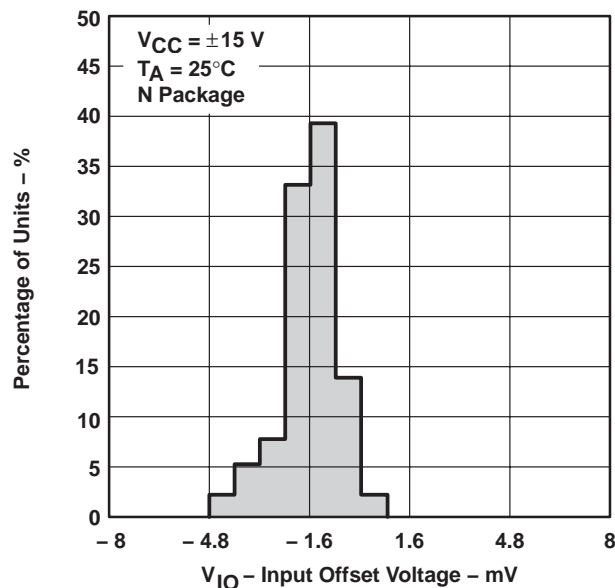


Figure 8

DISTRIBUTION OF TLE2071 INPUT OFFSET
 VOLTAGE TEMPERATURE COEFFICIENT

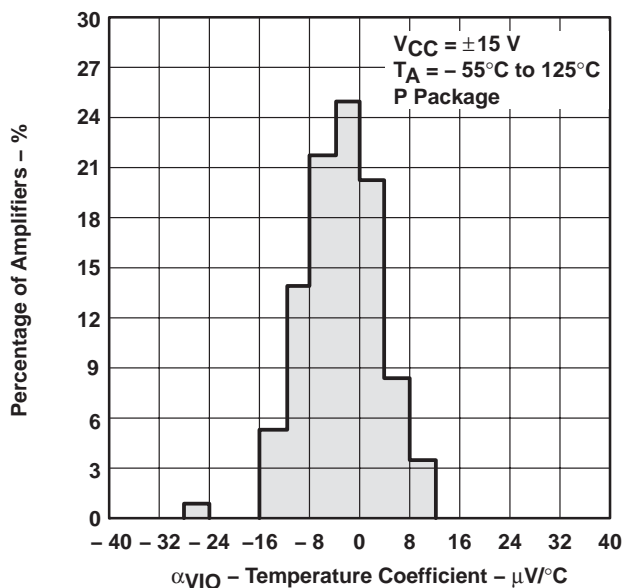


Figure 9

TLE207x, TLE207xA EXCALIBUR LOW-NOISE HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLE2072 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

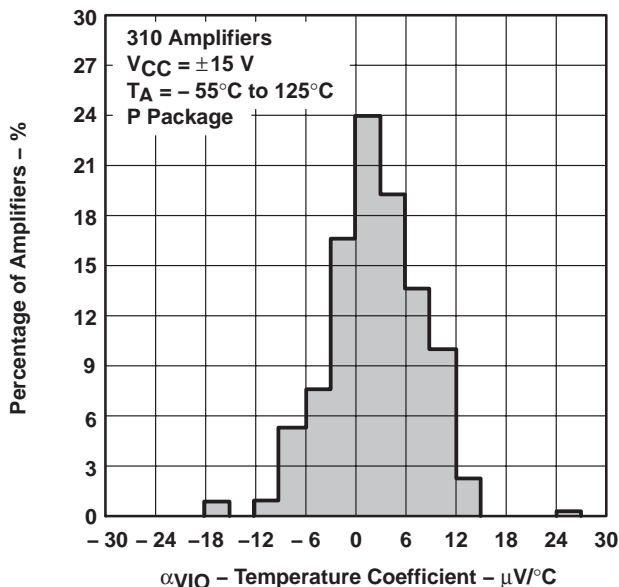


Figure 10

DISTRIBUTION OF TLE2074 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

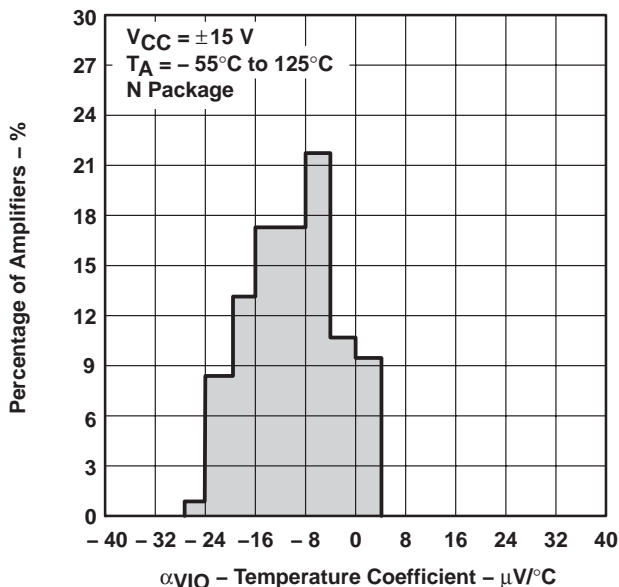


Figure 11

INPUT BIAS CURRENT AND INPUT OFFSET CURRENT†
vs
FREE-AIR TEMPERATURE

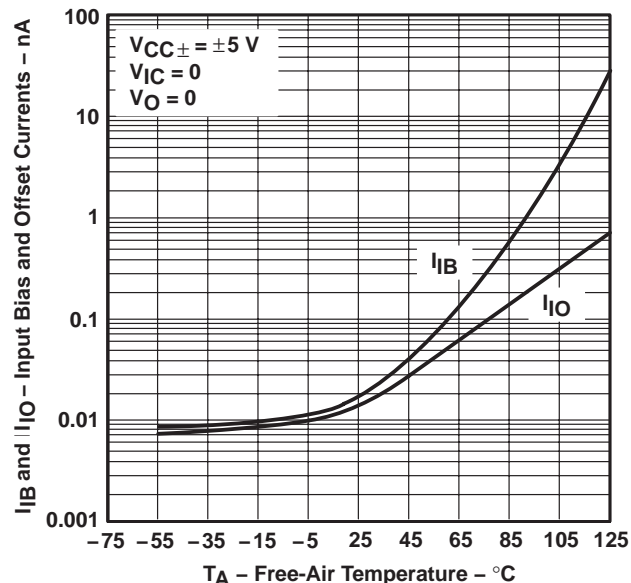


Figure 12

INPUT BIAS CURRENT AND INPUT OFFSET CURRENT†
vs
FREE-AIR TEMPERATURE

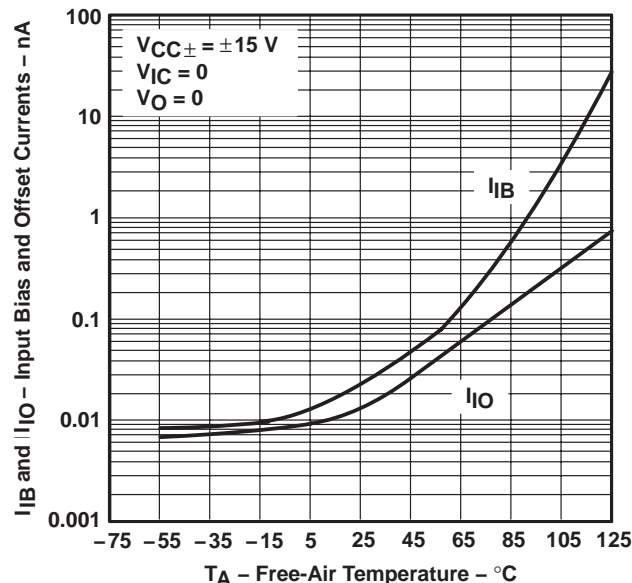
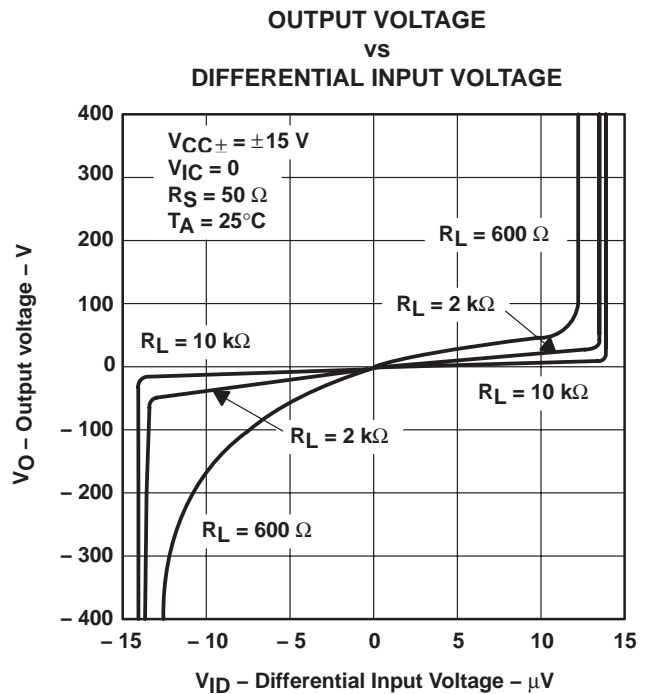
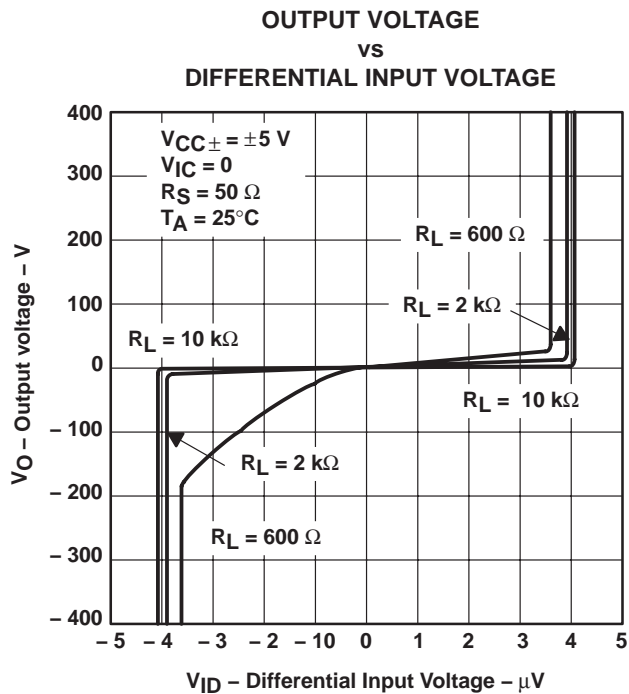
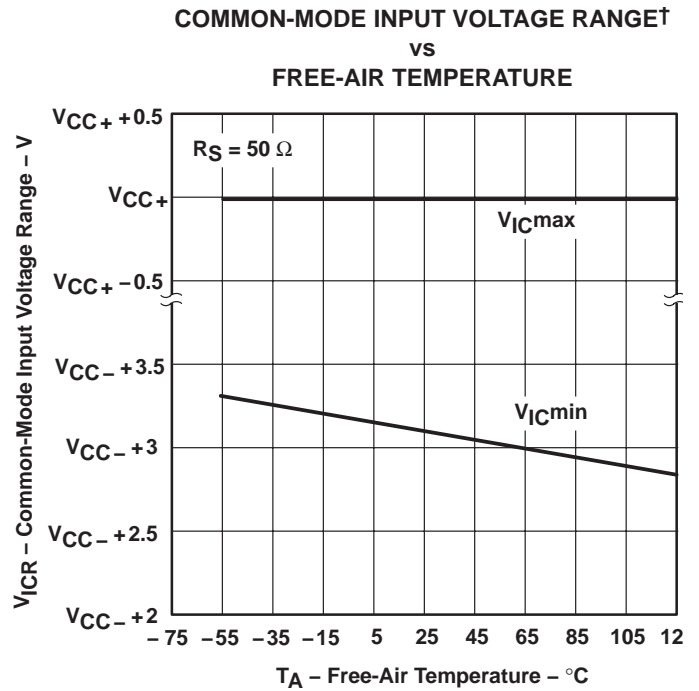
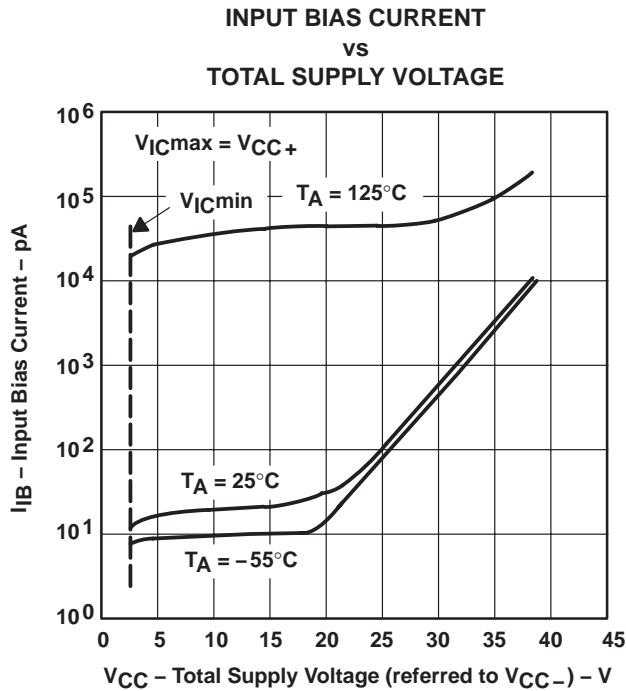


Figure 13

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE†
vs
OUTPUT CURRENT

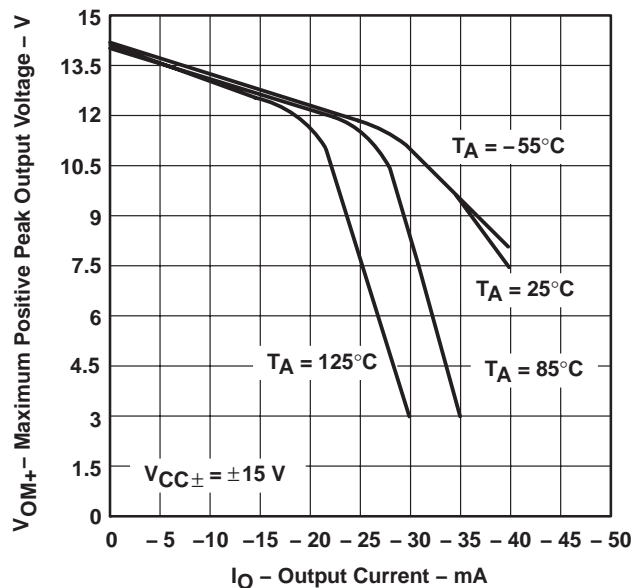


Figure 18

MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE†
vs
OUTPUT CURRENT

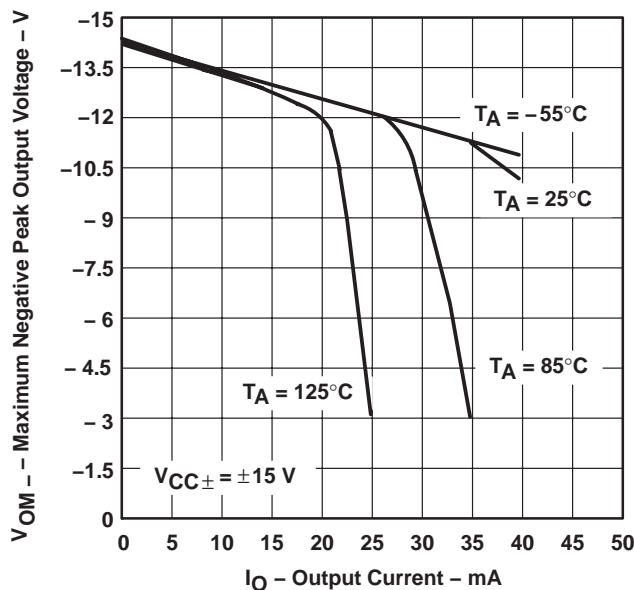


Figure 19

MAXIMUM PEAK OUTPUT VOLTAGE†
vs
FREE-AIR TEMPERATURE

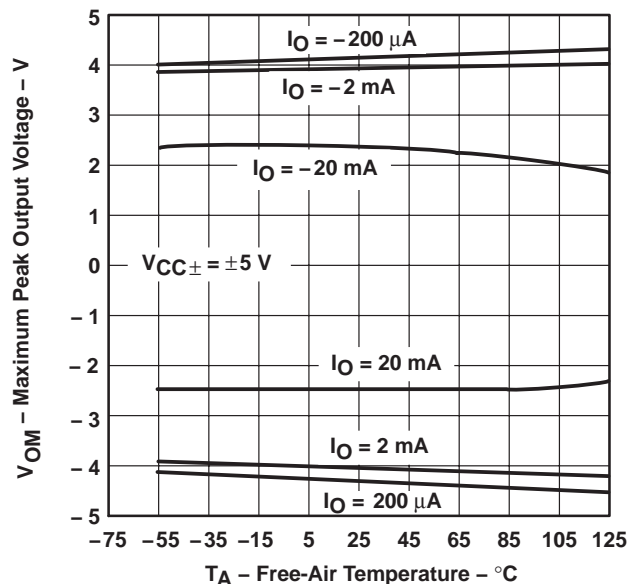


Figure 20

MAXIMUM PEAK OUTPUT VOLTAGE†
vs
FREE-AIR TEMPERATURE

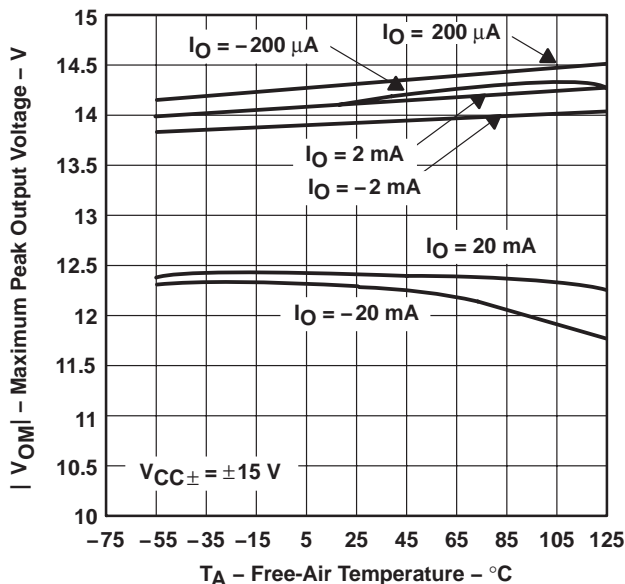
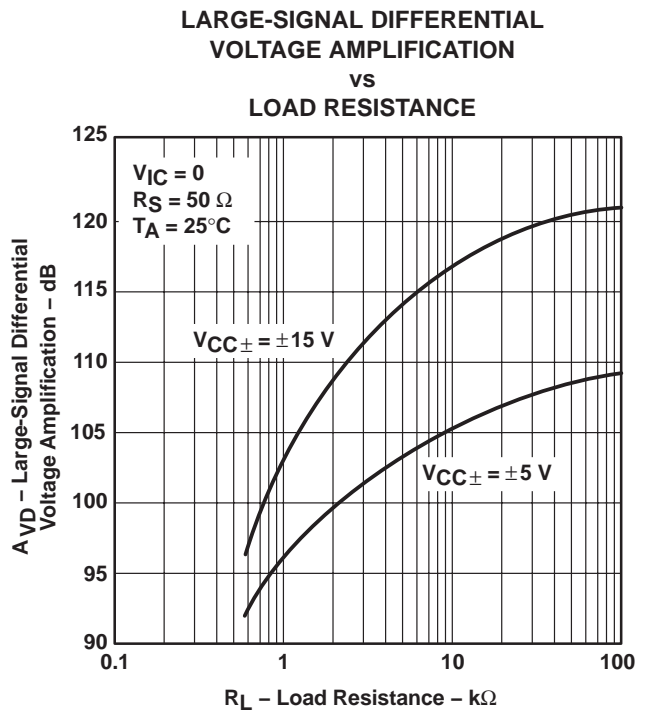
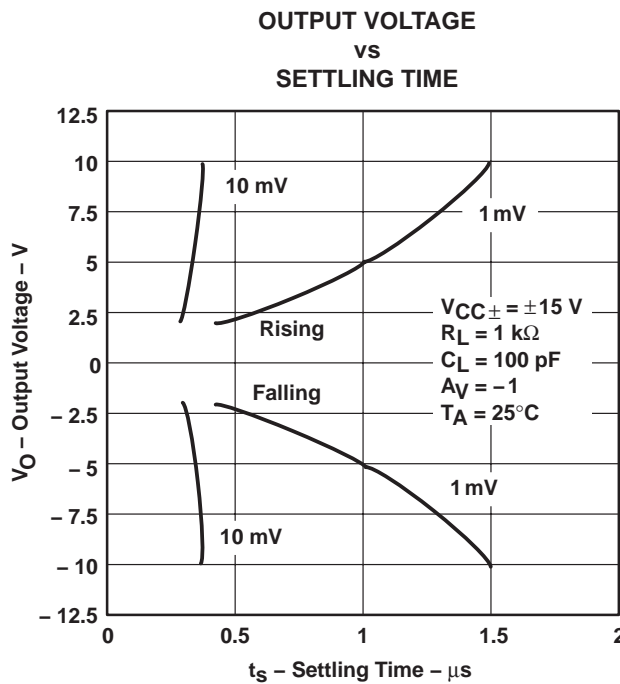
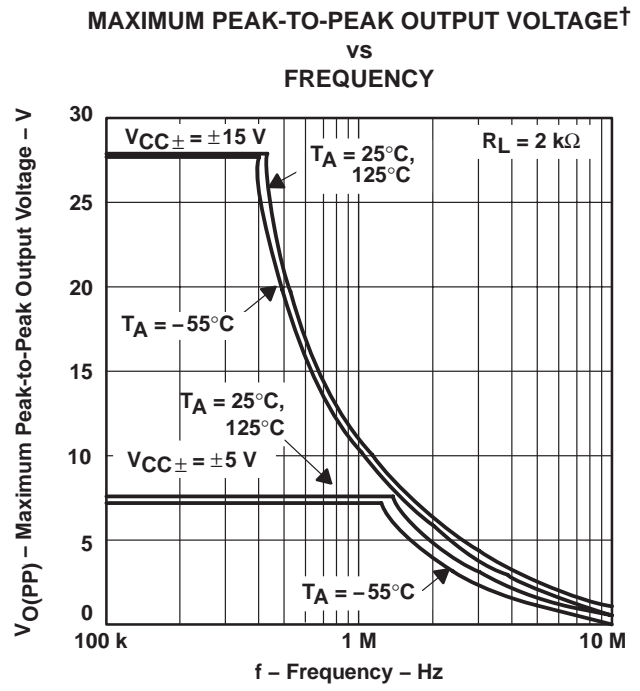
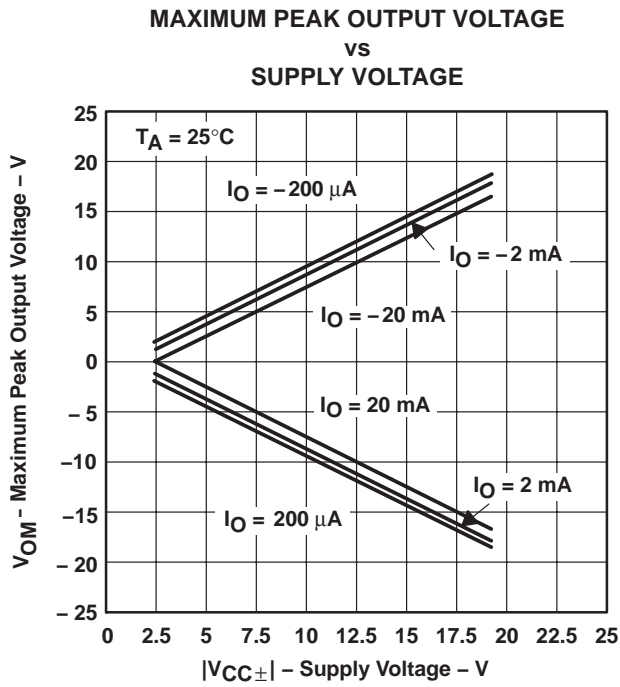


Figure 21

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

**LARGE-SIGNAL DIFFERENTIAL
 VOLTAGE AMPLIFICATION†**
 vs
FREE-AIR TEMPERATURE

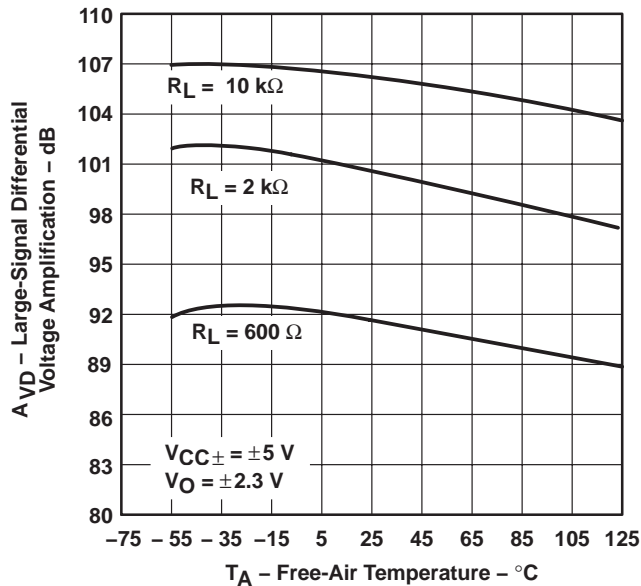


Figure 26

**LARGE-SIGNAL DIFFERENTIAL
 VOLTAGE AMPLIFICATION†**
 vs
FREE-AIR TEMPERATURE

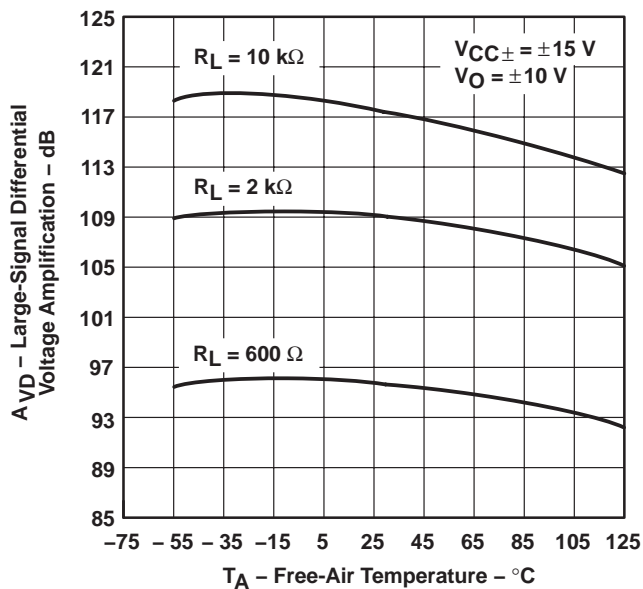


Figure 27

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

**SMALL-SIGNAL DIFFERENTIAL VOLTAGE
 AMPLIFICATION AND PHASE SHIFT**

vs

FREQUENCY

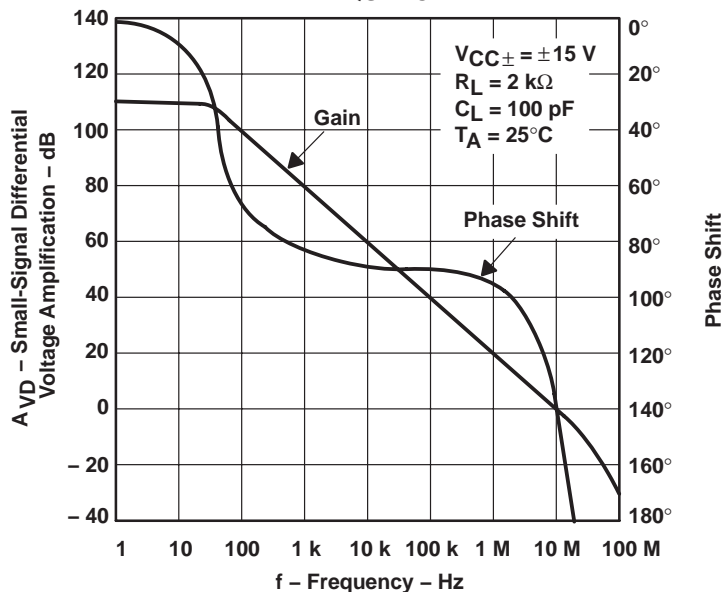


Figure 28

**SMALL-SIGNAL DIFFERENTIAL VOLTAGE
 AMPLIFICATION AND PHASE SHIFT**

vs

FREQUENCY

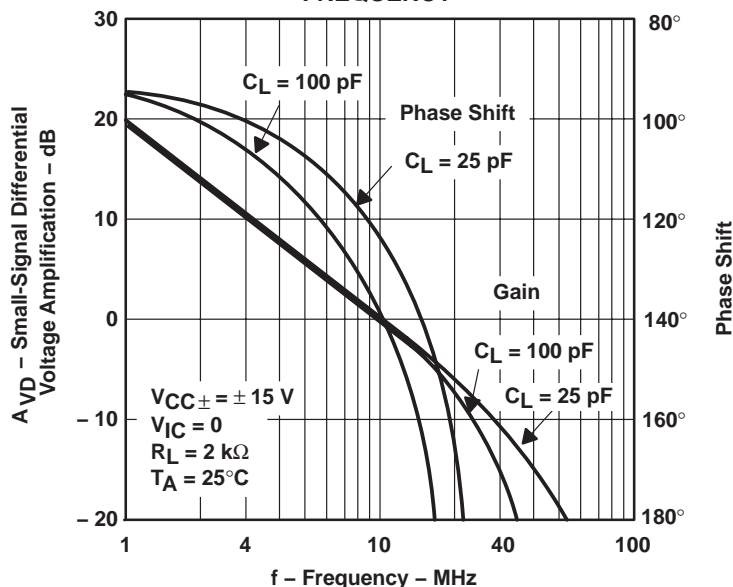


Figure 29

TLE207x, TLE207xA EXCALIBUR LOW-NOISE HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

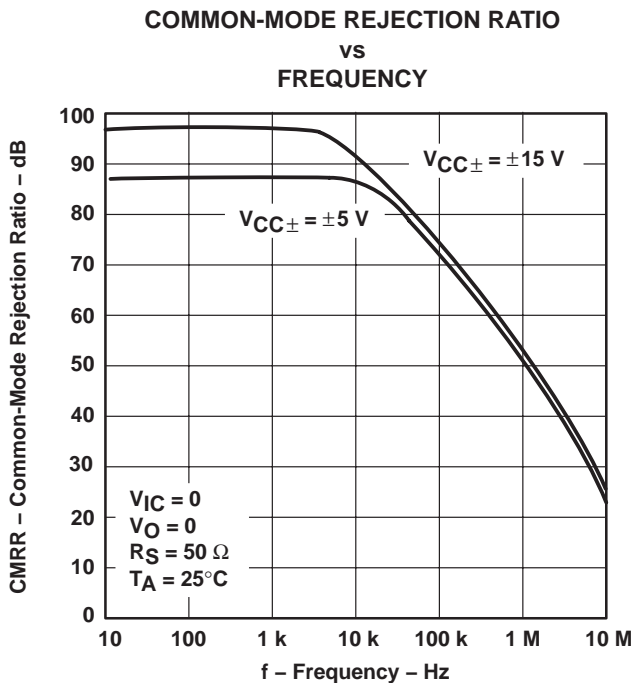


Figure 30

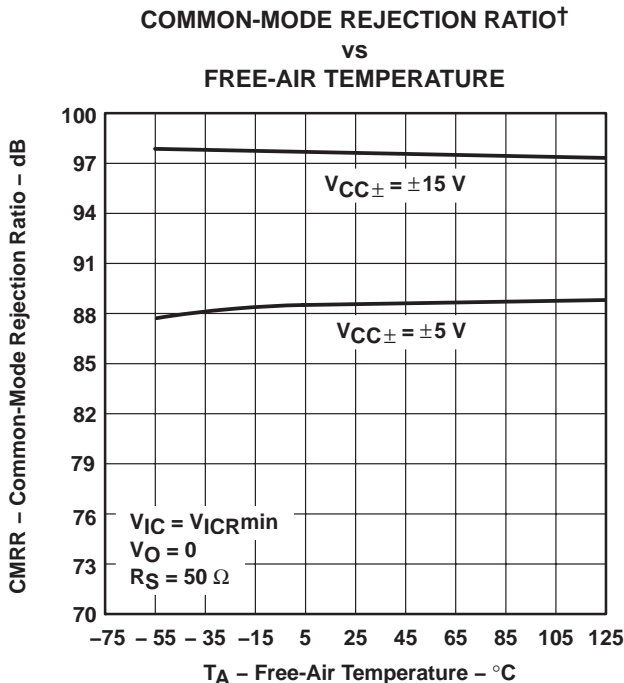


Figure 31

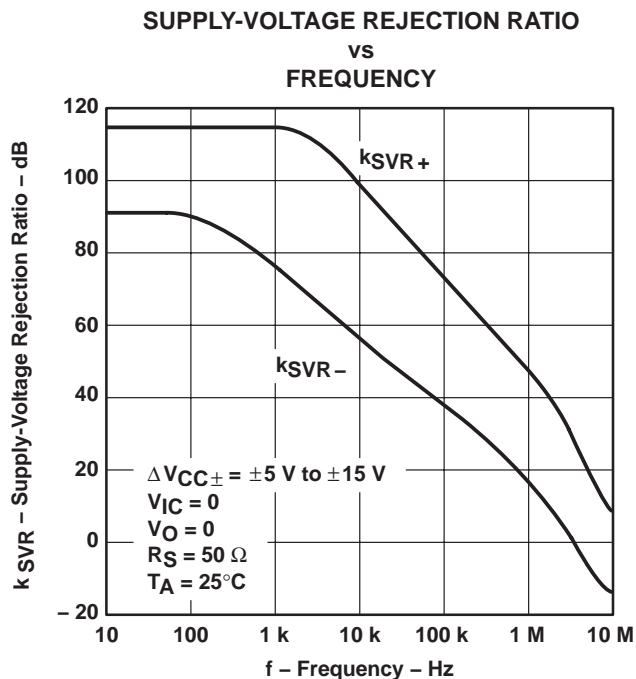


Figure 32

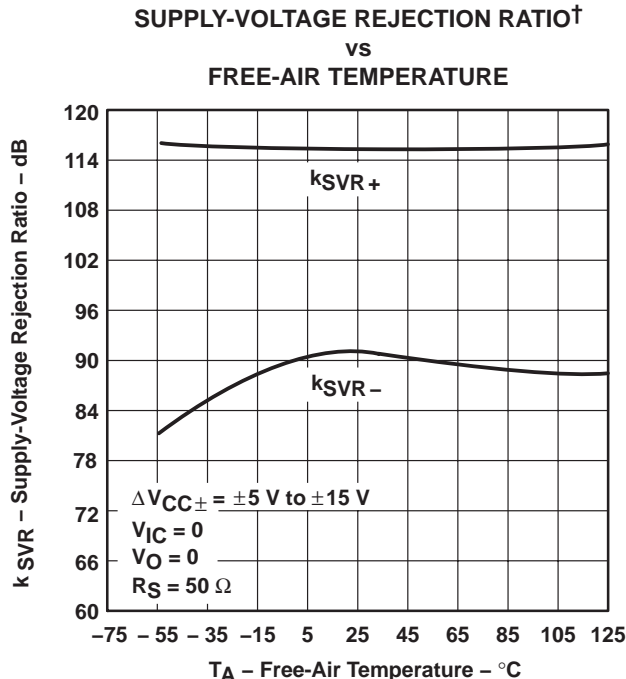
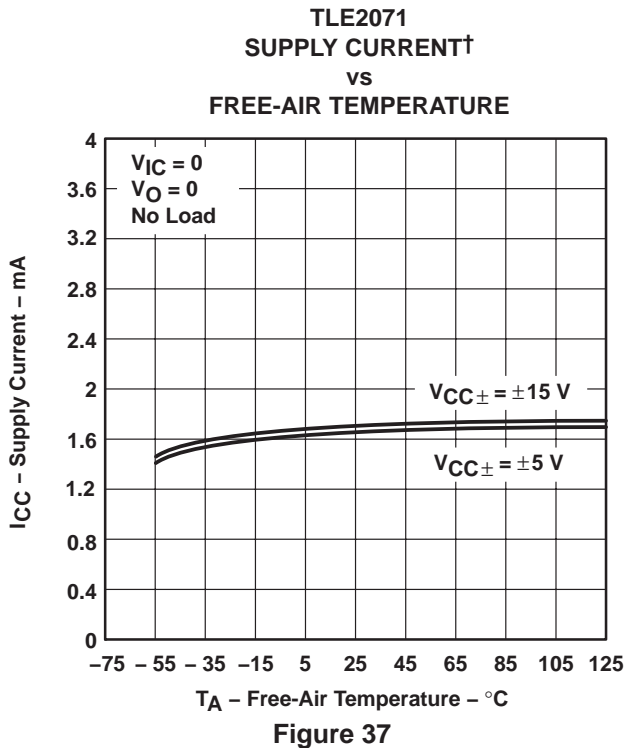
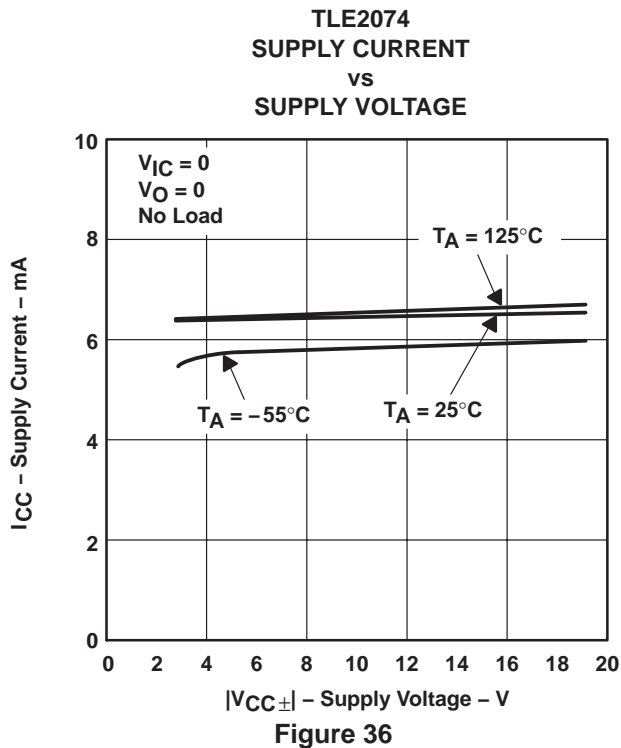
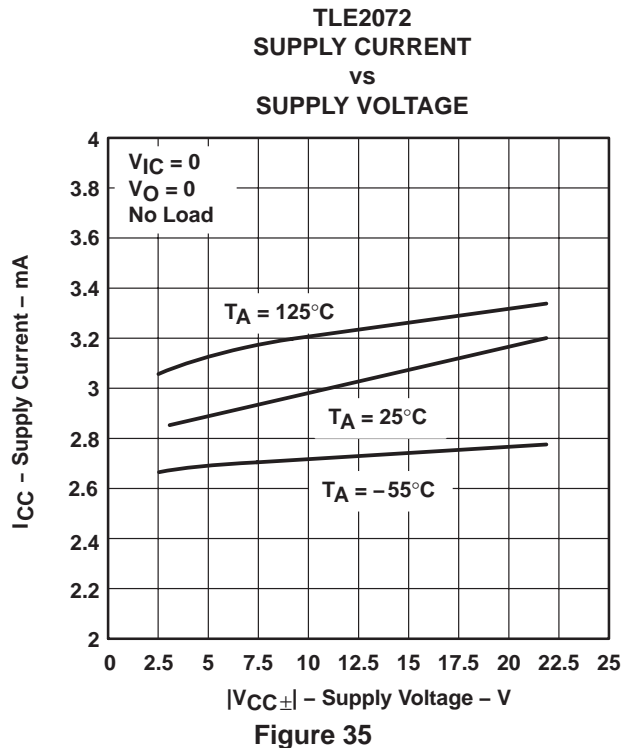
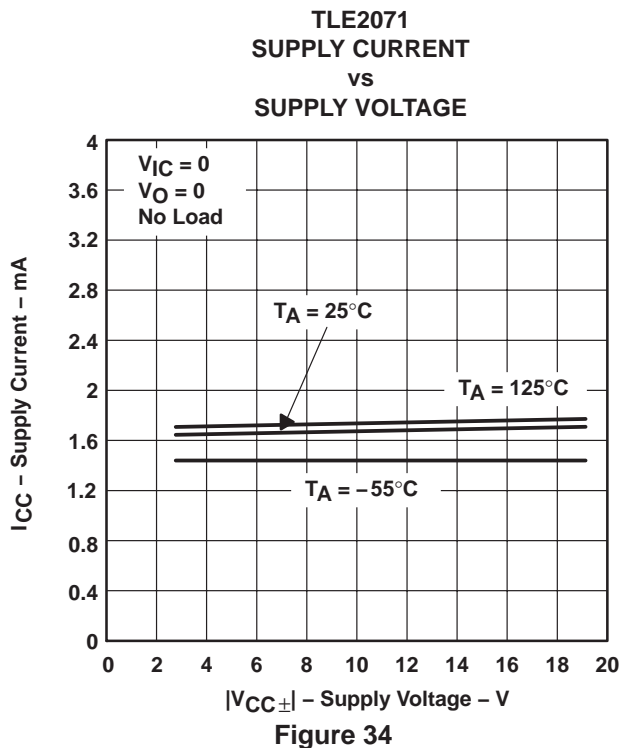


Figure 33

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

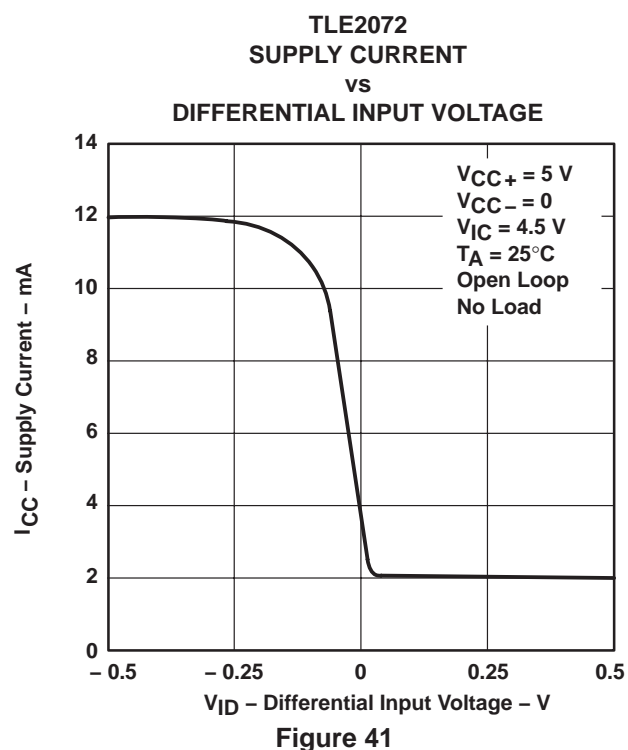
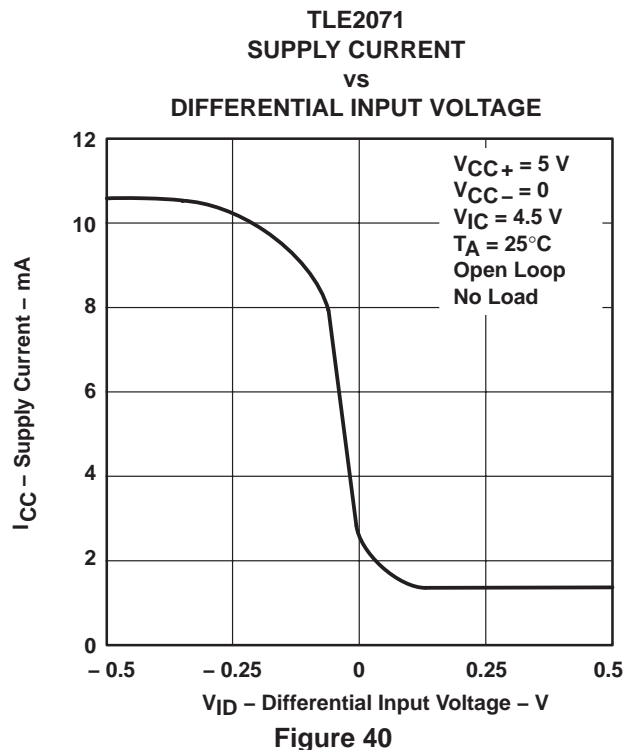
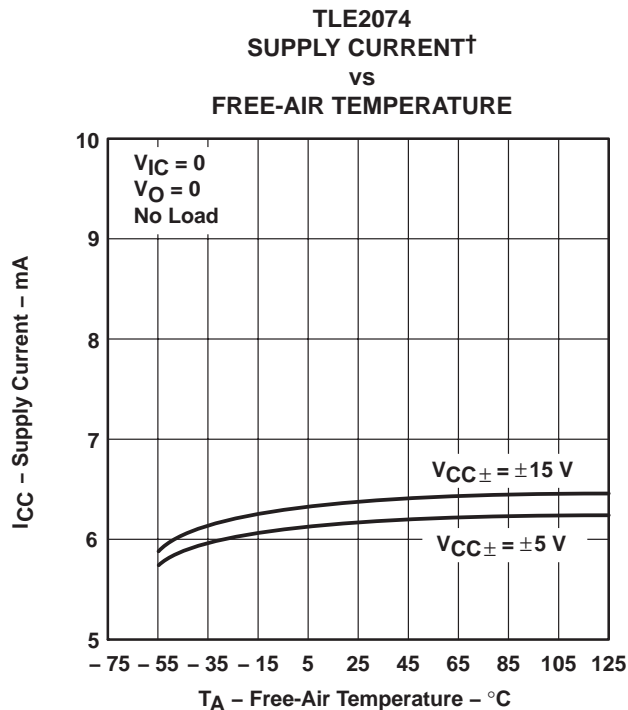
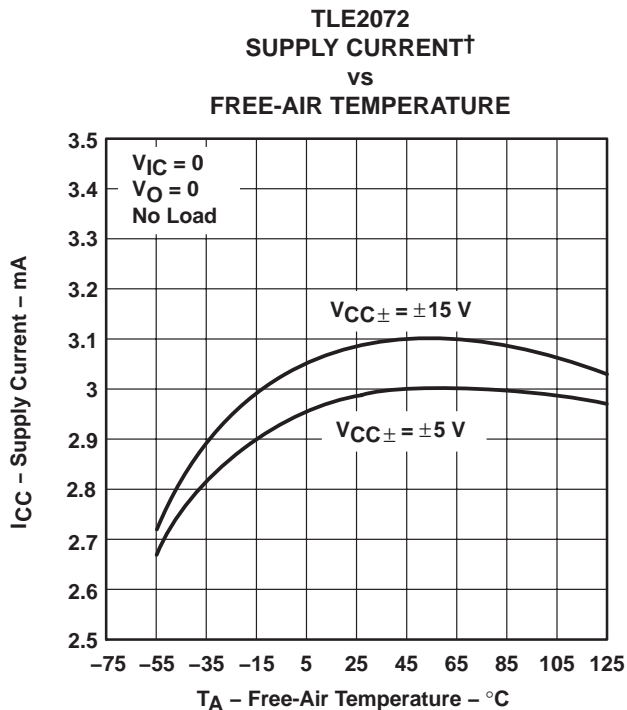


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TYPICAL CHARACTERISTICS

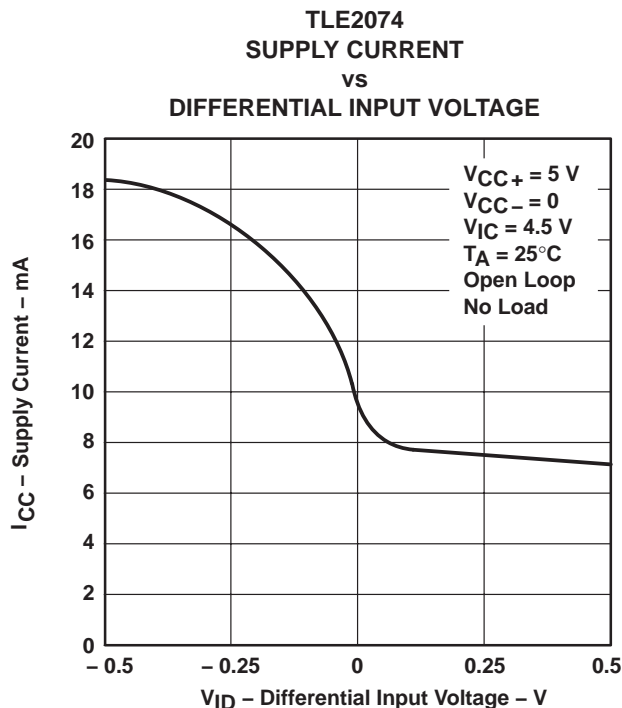


Figure 42

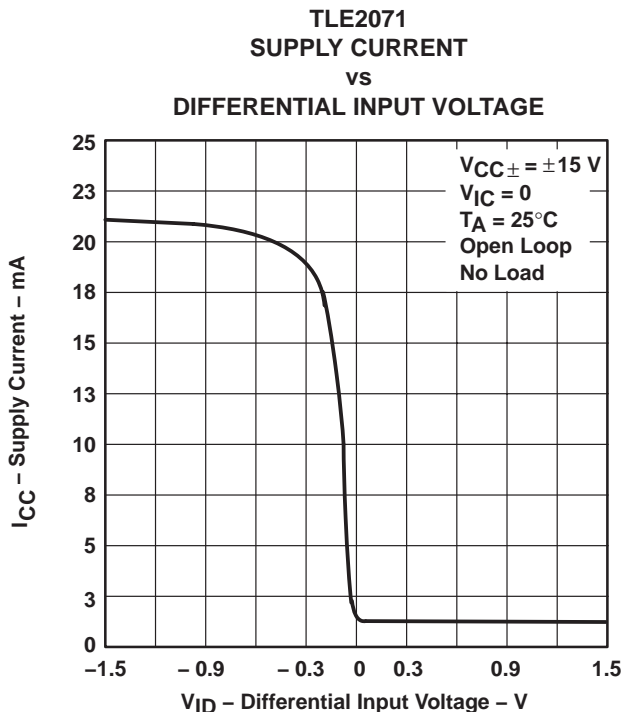


Figure 43

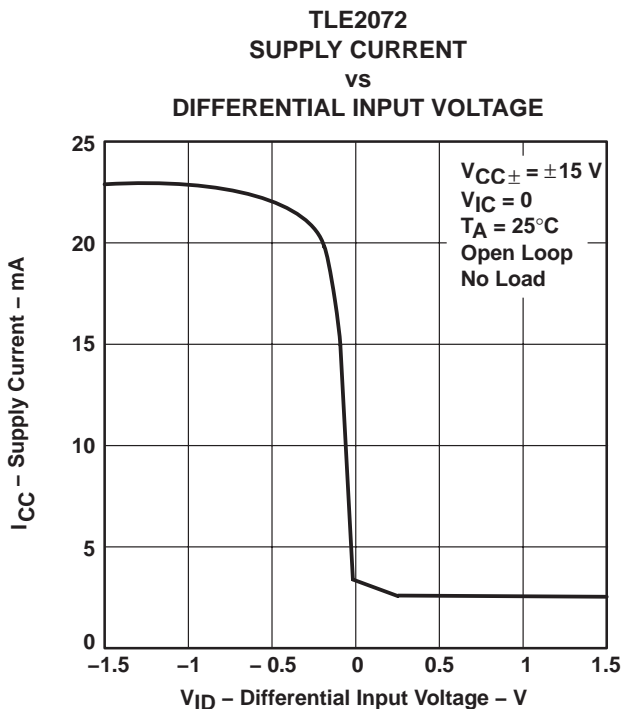


Figure 44

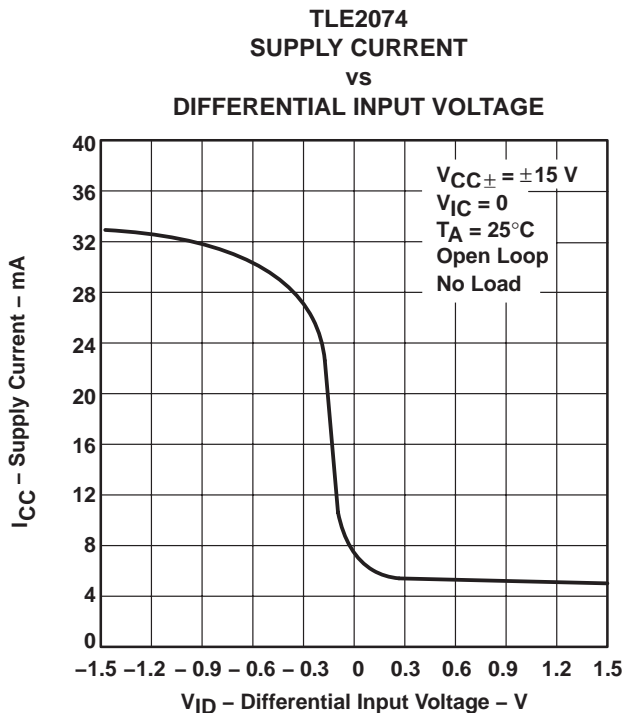


Figure 45

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TYPICAL CHARACTERISTICS

SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE

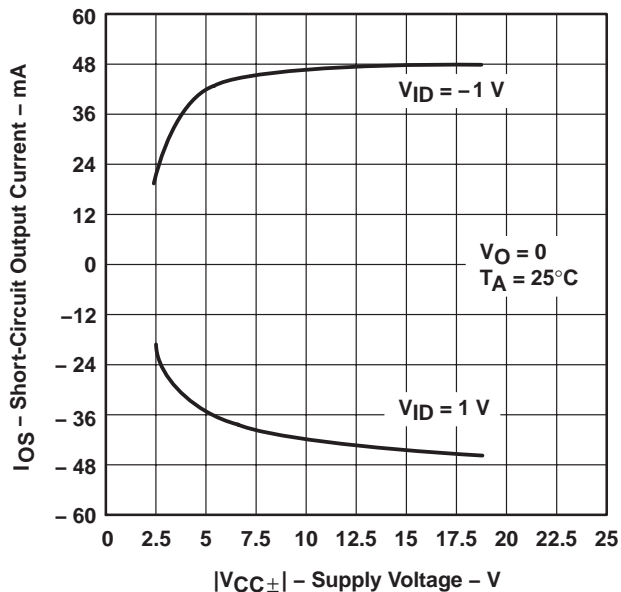


Figure 46

SHORT-CIRCUIT OUTPUT CURRENT
vs
ELAPSED TIME

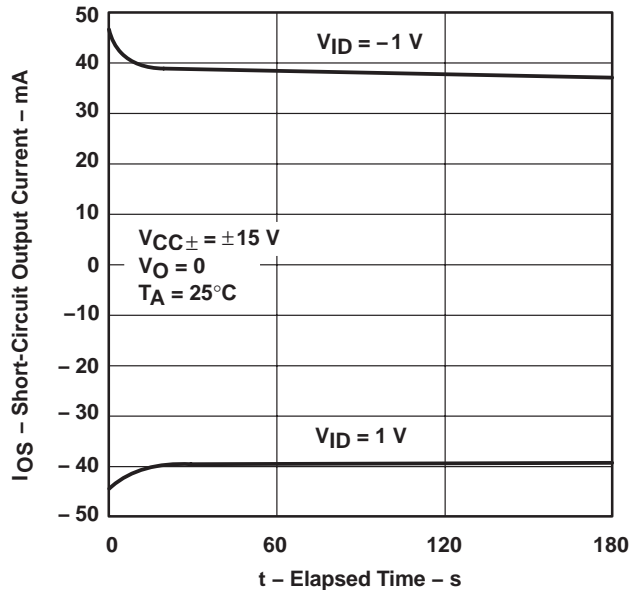


Figure 47

SHORT-CIRCUIT OUTPUT CURRENT†
vs
FREE-AIR TEMPERATURE

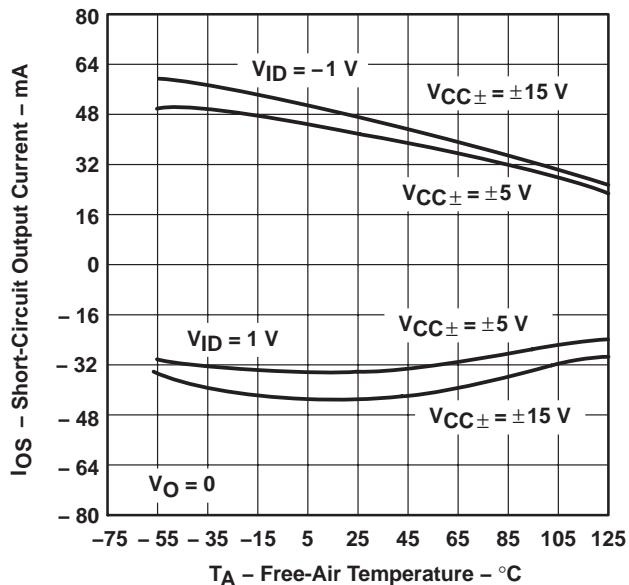


Figure 48

SLEW RATE†
vs
FREE-AIR TEMPERATURE

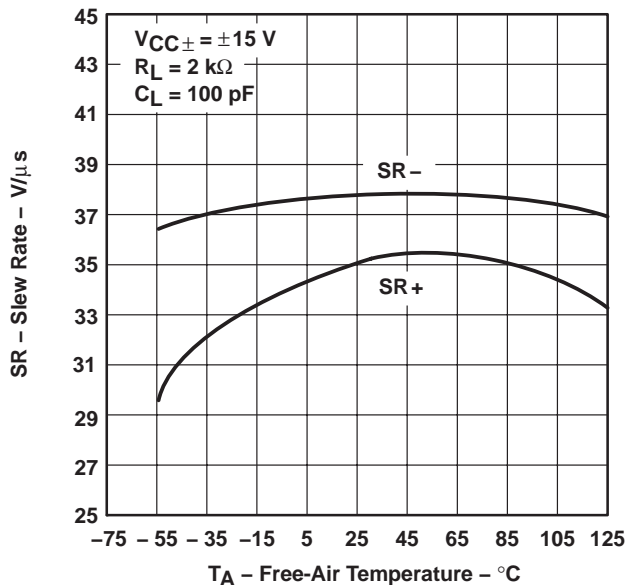


Figure 49

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

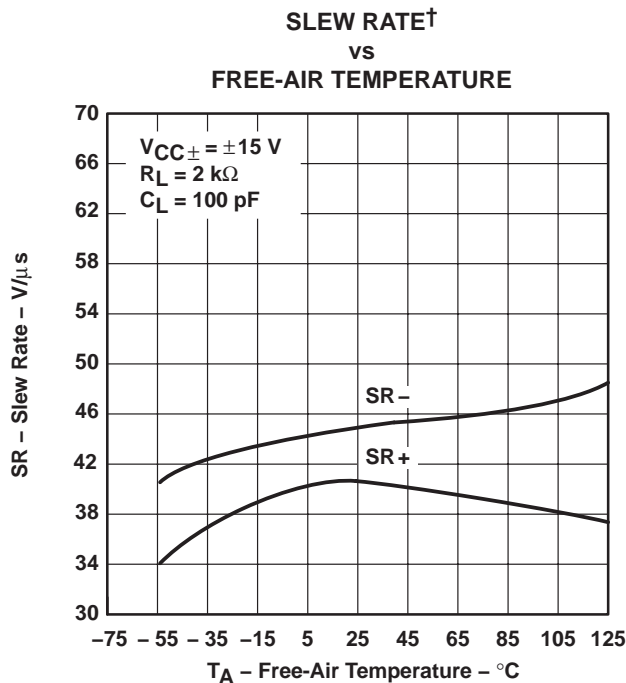


Figure 50

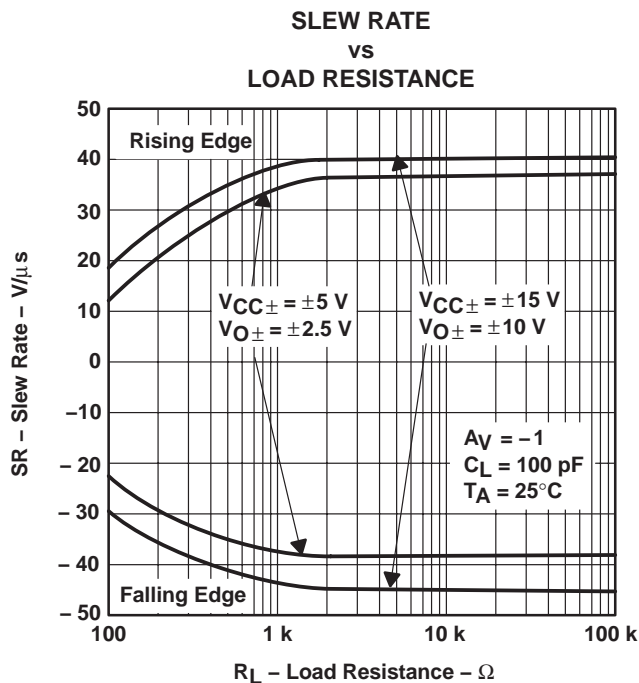


Figure 51

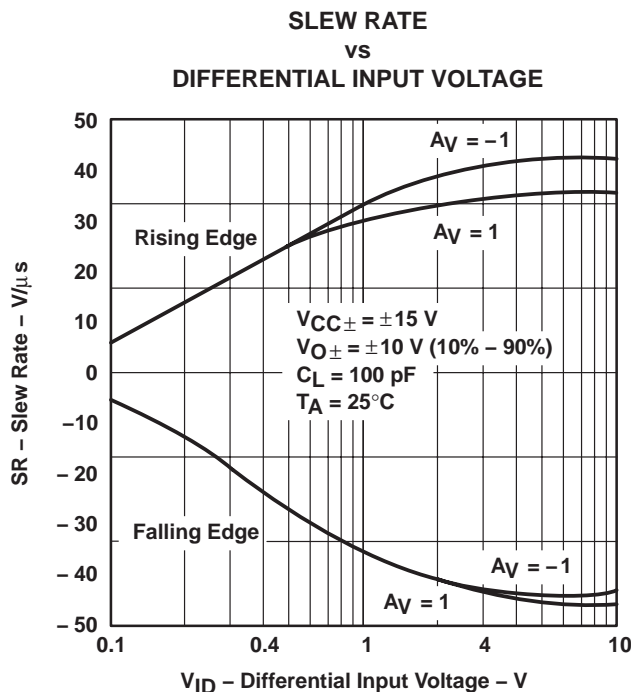


Figure 52

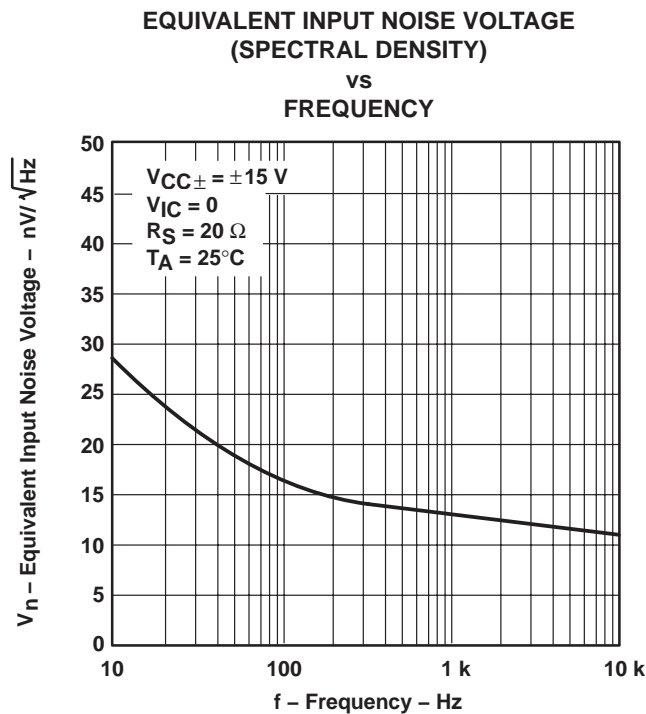


Figure 53

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

INPUT-REFERRED NOISE VOLTAGE
vs
NOISE BANDWIDTH

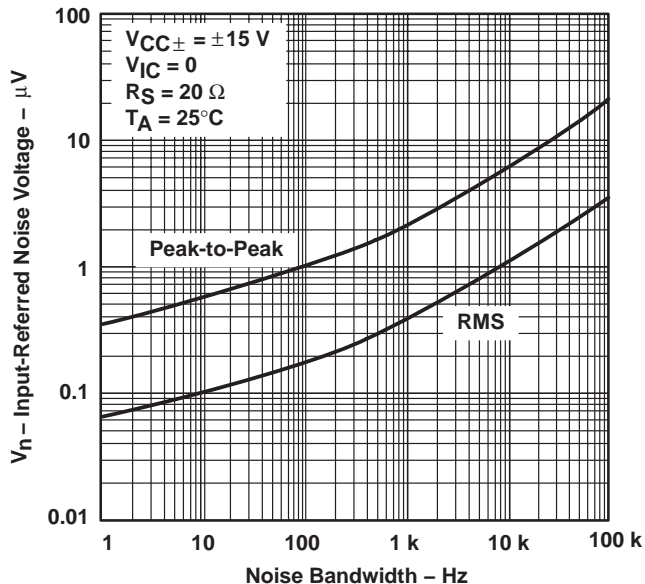


Figure 54

INPUT-REFERRED NOISE VOLTAGE
OVER A 10-SECOND TIME INTERVAL

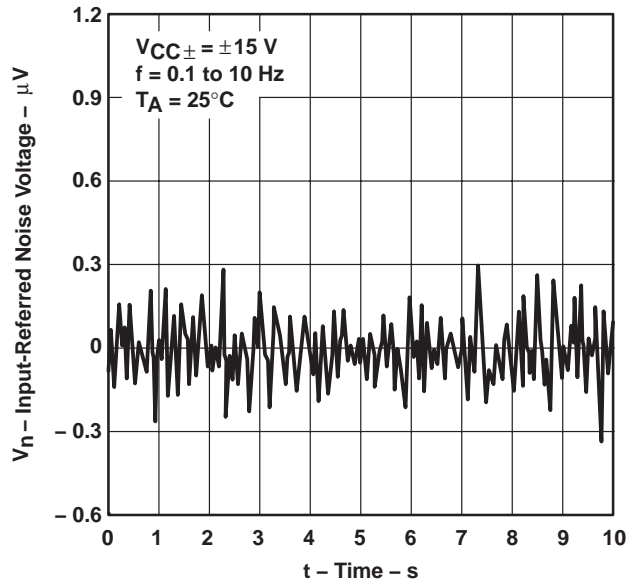


Figure 55

THIRD-OCTAVE SPECTRAL NOISE DENSITY
vs
FREQUENCY BANDS

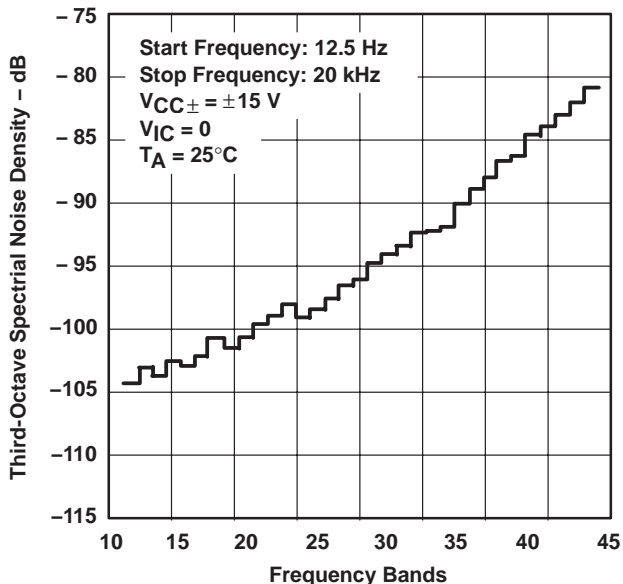


Figure 56

TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY

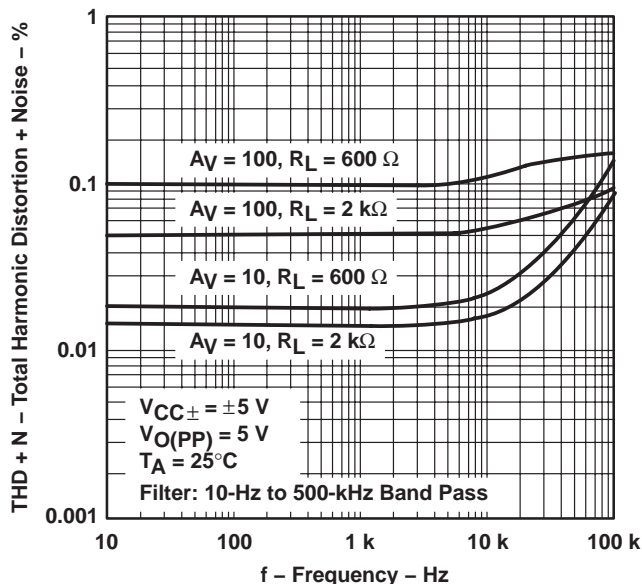


Figure 57

TYPICAL CHARACTERISTICS

**TOTAL HARMONIC DISTORTION PLUS NOISE
 vs
 FREQUENCY**

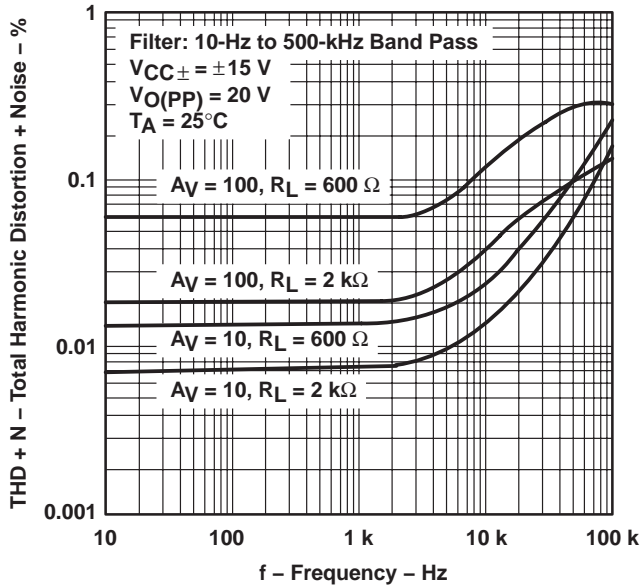


Figure 58

**UNITY-GAIN BANDWIDTH
 vs
 LOAD CAPACITANCE**

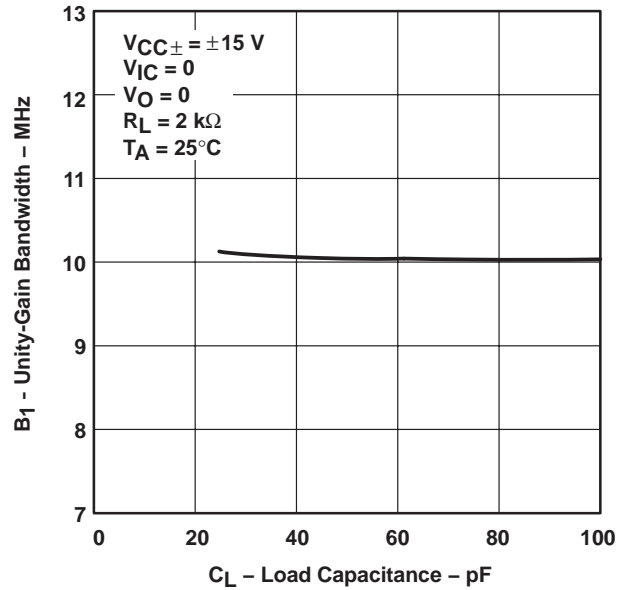


Figure 59

**GAIN-BANDWIDTH PRODUCT†
 vs
 FREE-AIR TEMPERATURE**

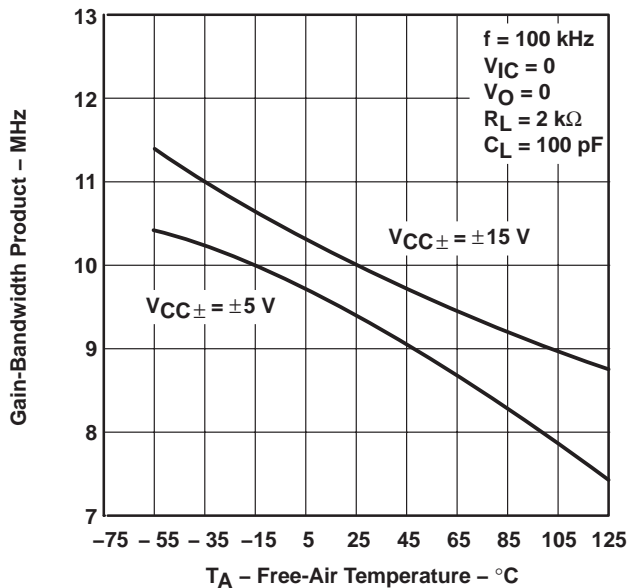


Figure 60

**GAIN-BANDWIDTH PRODUCT
 vs
 SUPPLY VOLTAGE**

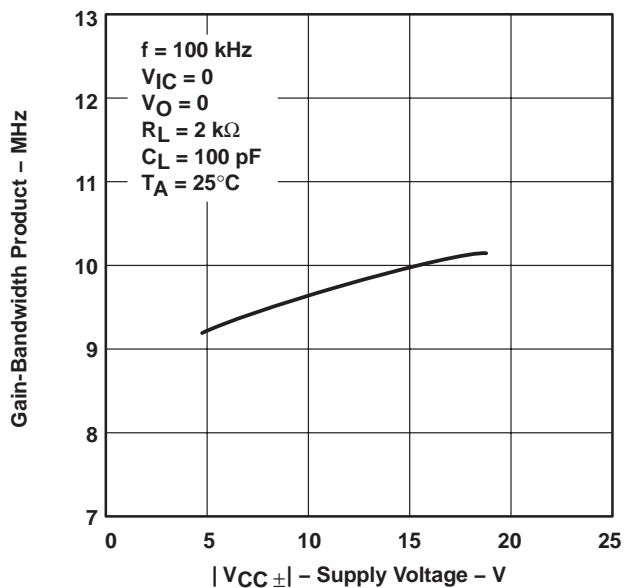


Figure 61

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE207x, TLE207xA EXCALIBUR LOW-NOISE HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

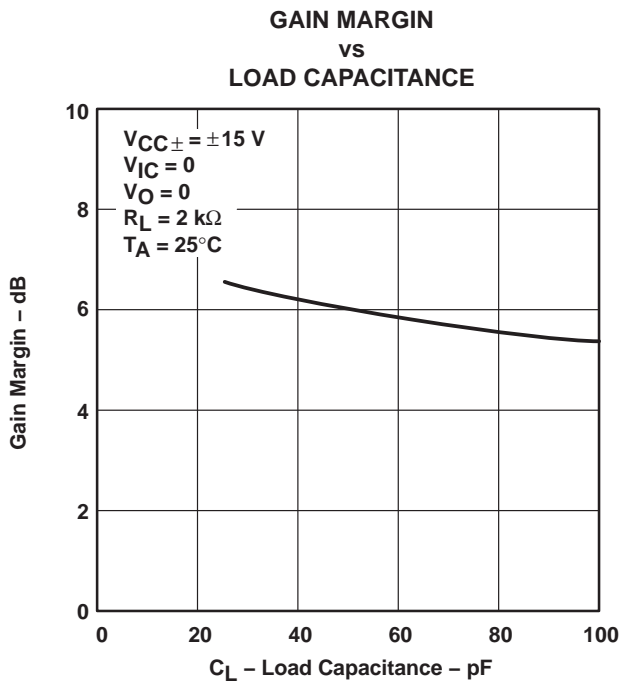


Figure 62

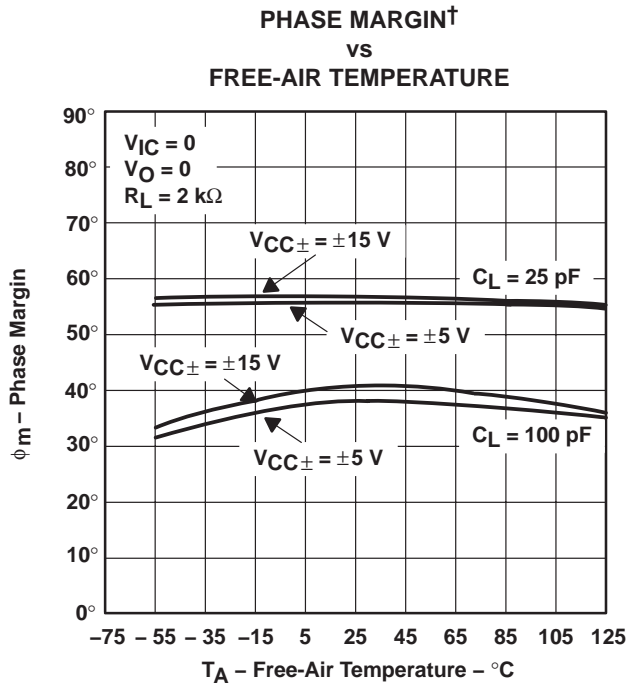


Figure 63

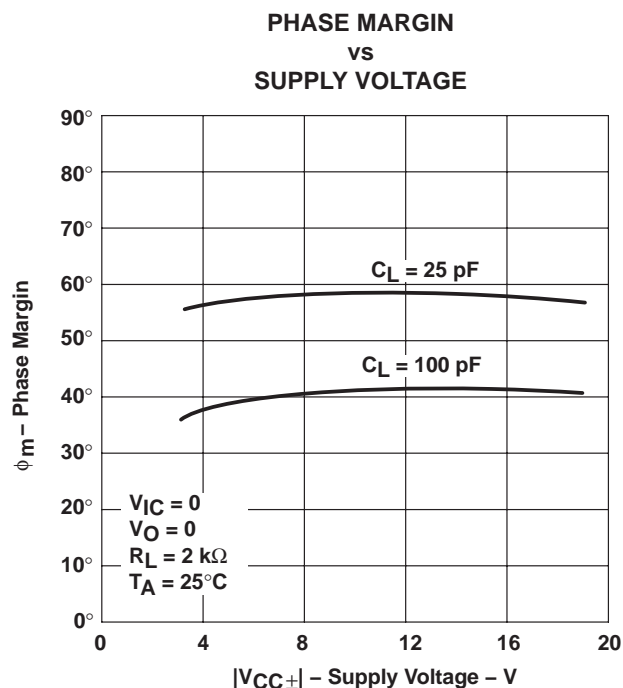


Figure 64

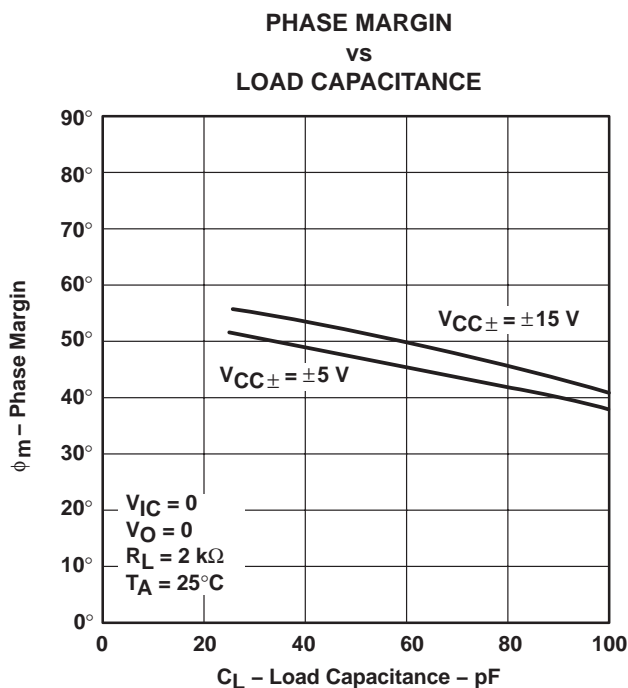


Figure 65

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

NONINVERTING LARGE-SIGNAL
 PULSE RESPONSE†

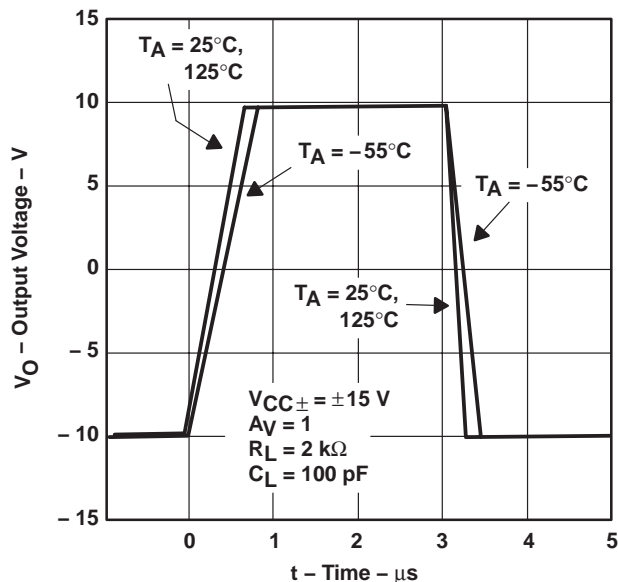


Figure 66

SMALL-SIGNAL PULSE RESPONSE

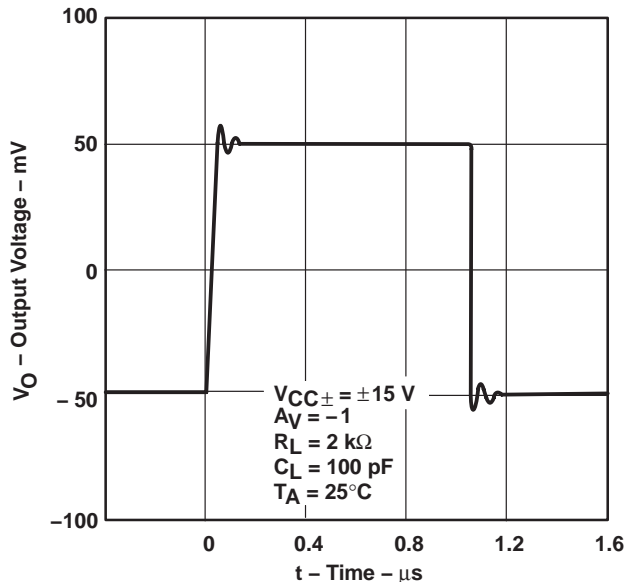


Figure 67

CLOSED-LOOP OUTPUT IMPEDANCE
 vs
 FREQUENCY

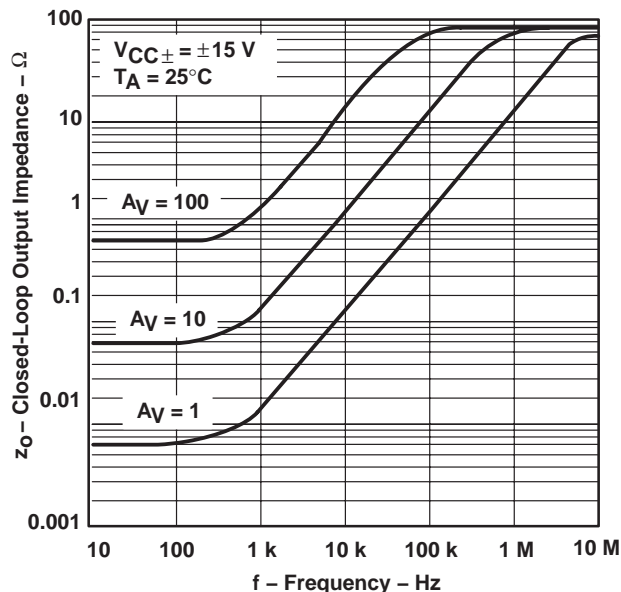


Figure 68

TLE2072 AND TLE2074
 CROSSTALK ATTENUATION
 vs
 FREQUENCY

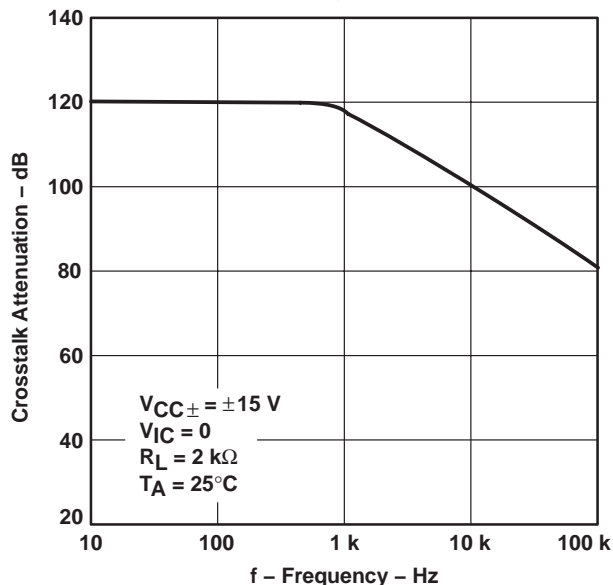


Figure 69

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE207x, TLE207xA EXCALIBUR LOW-NOISE HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS181B – FEBRUARY 1997 – REVISED APRIL 2004

APPLICATION INFORMATION

input characteristics

The TLE207x, TLE207xA, and TLE207xB are specified with a minimum and a maximum input voltage that if exceeded at either input could cause the device to malfunction. Because of the extremely high input impedance and resulting low bias current requirements, the TLE207x, TLE207xA, and TLE207xB are well suited for low-level signal processing; however, leakage currents on printed-circuit boards and sockets can easily exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 70). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.

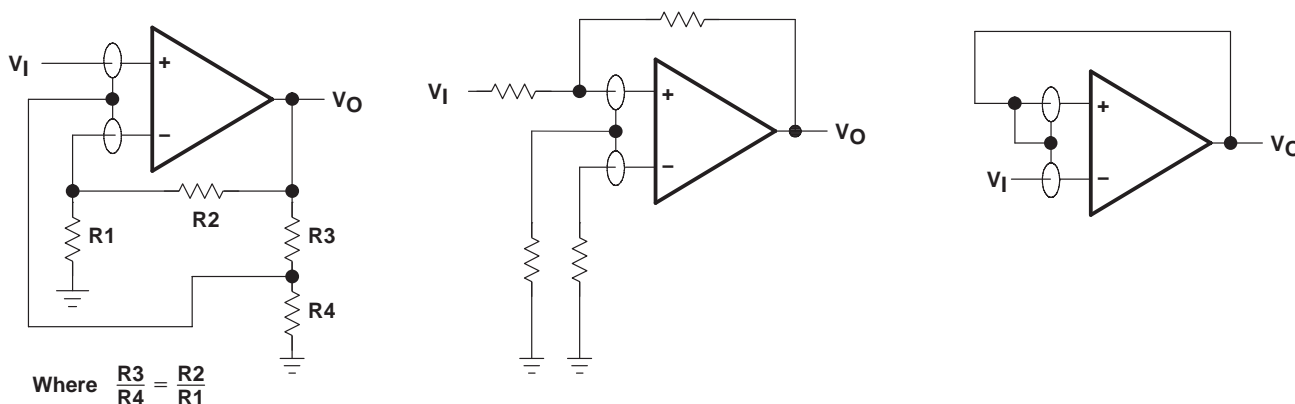


Figure 70. Use of Guard Rings

TLE2071 input offset voltage nulling

The TLE2071 series offers external null pins that can be used to further reduce the input offset voltage. The circuit of Figure 71 can be connected as shown if the feature is desired. When external nulling is not needed, the null pins may be left unconnected.

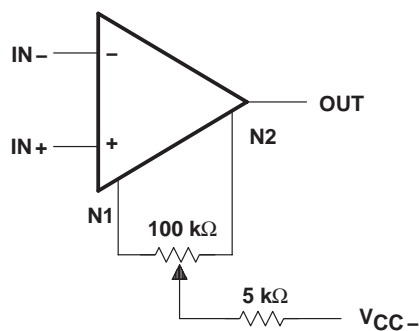


Figure 71. Input Offset Voltage Nulling

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using *PSpice™ Parts™* model generation software. The Boyle macromodel (see Note 4) and subcircuit Figure 72 were generated using the TLE207x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G.R. Boyle, B.M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

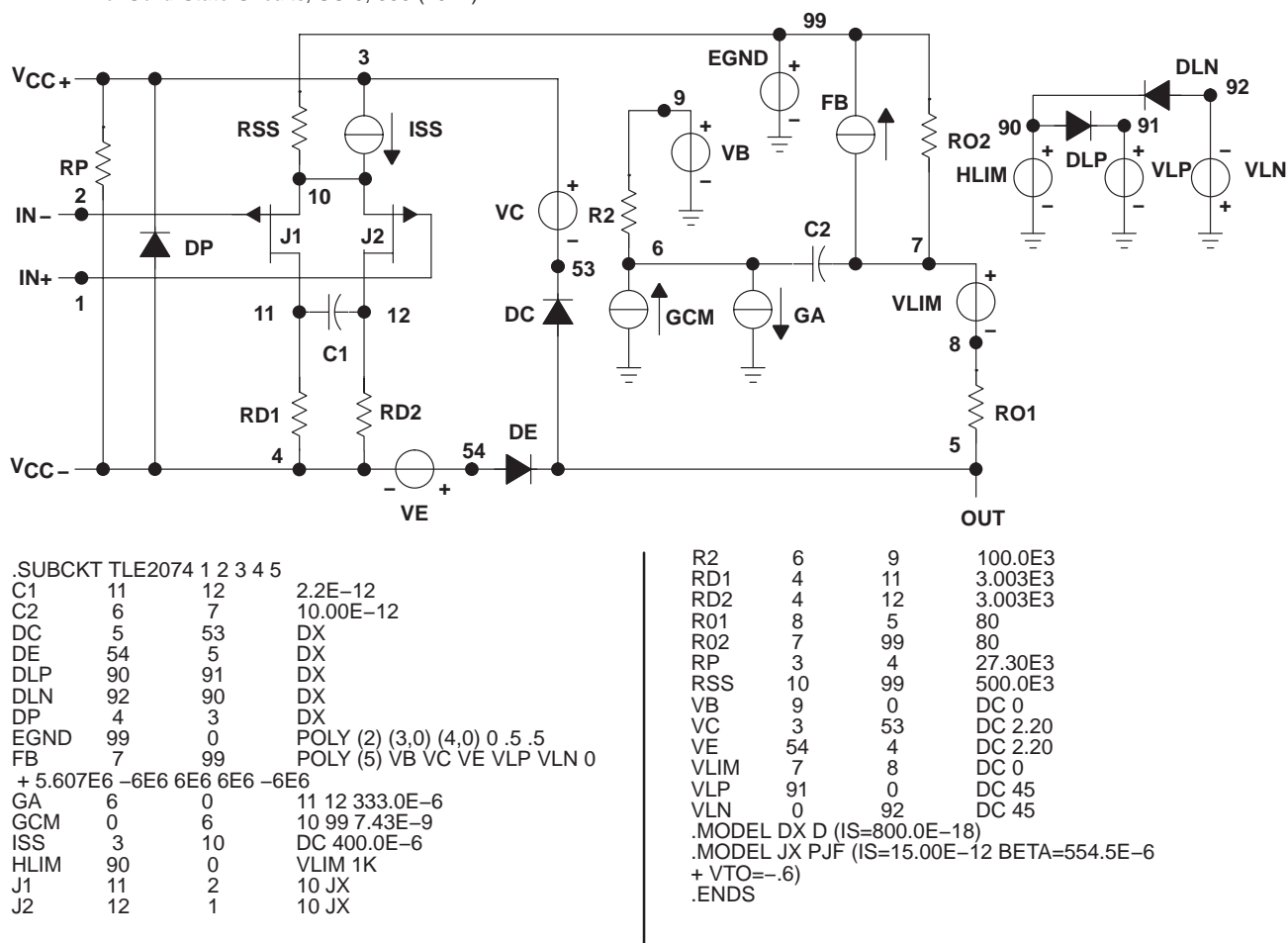


Figure 72. Boyle Macromodel and Subcircuit

PSpice and *Parts* are trademarks of MicroSim Corporation.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-9460201Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9460201QHA	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460201QPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460202Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9460202QHA	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460202QPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460203Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9460203QCA	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460203QDA	ACTIVE	CFP	W	14	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460204Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9460204QHA	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460204QPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460205Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9460205QHA	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460205QPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460206Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9460206QCA	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9460206QDA	ACTIVE	CFP	W	14	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2071ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071ACDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071ACDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071ACP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071ACPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLE2071AMJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2071AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2071AMUB	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TLE2071CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071CDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TLE2071CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2071IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2071MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLE2071MJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2071MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2071MUB	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2072ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072ACP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072ACPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLE2072AMJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2072AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2072AMUB	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2072CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						no Sb/Br)		
TLE2072CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2072IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2072MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLE2072MJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2072MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2072MUB	ACTIVE	CFP	U	10	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2074ACDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074ACDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074ACDWR	OBSOLETE	SOIC	DW	16		TBD	Call TI	Call TI
TLE2074ACN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074ACNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074AIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074AIDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074AIDWR	OBSOLETE	SOIC	DW	16		TBD	Call TI	Call TI
TLE2074AIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074AINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLE2074AMJ	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2074AMJB	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2074AMWB	ACTIVE	CFP	W	14	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2074CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074CDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TLE2074CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074CDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074IDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074IDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2074IDWR	OBSOLETE	SOIC	DW	16		TBD	Call TI	Call TI
TLE2074IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074INE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLE2074MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLE2074MJ	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2074MJB	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
TLE2074MWB	ACTIVE	CFP	W	14	1	TBD	A42 SNPB	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

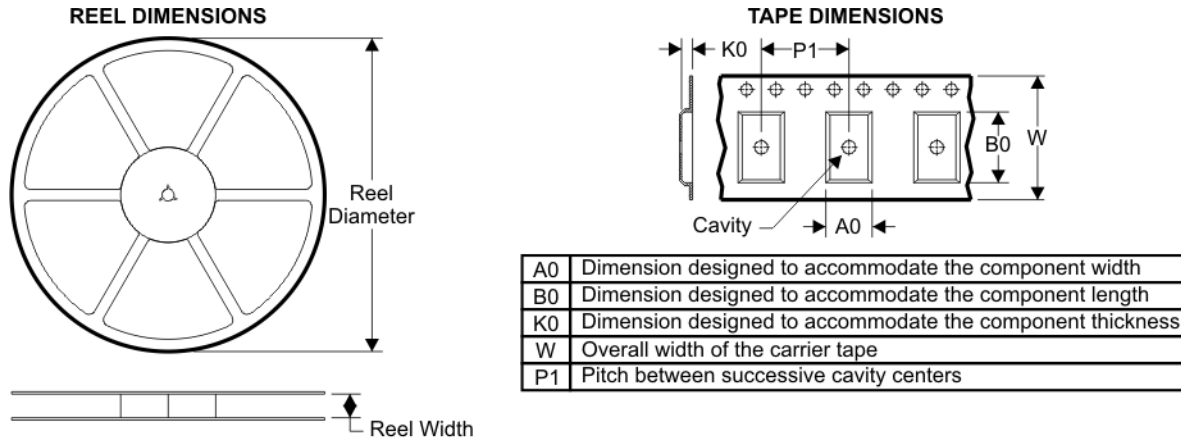
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL BOX INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2071ACDR	D	8	SITE 60	330	12	6.4	5.2	2.1	8	12	Q1
TLE2071AIDR	D	8	SITE 60	330	12	6.4	5.2	2.1	8	12	Q1
TLE2071IDR	D	8	SITE 60	330	12	6.4	5.2	2.1	8	12	Q1
TLE2072AIDR	D	8	SITE 60	330	12	6.4	5.2	2.1	8	12	Q1
TLE2072CDR	D	8	SITE 60	330	12	6.4	5.2	2.1	8	12	Q1
TLE2074CDWR	DW	16	SITE 60	330	16	10.75	10.7	2.7	12	16	Q1

TAPE AND REEL BOX DIMENSIONS



Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
TLE2071ACDR	D	8	SITE 60	346.0	346.0	29.0
TLE2071AIDR	D	8	SITE 60	346.0	346.0	29.0
TLE2071IDR	D	8	SITE 60	346.0	346.0	29.0
TLE2072AIDR	D	8	SITE 60	346.0	346.0	29.0
TLE2072CDR	D	8	SITE 60	346.0	346.0	29.0
TLE2074CDWR	DW	16	SITE 60	346.0	346.0	33.0

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP1-T8

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)

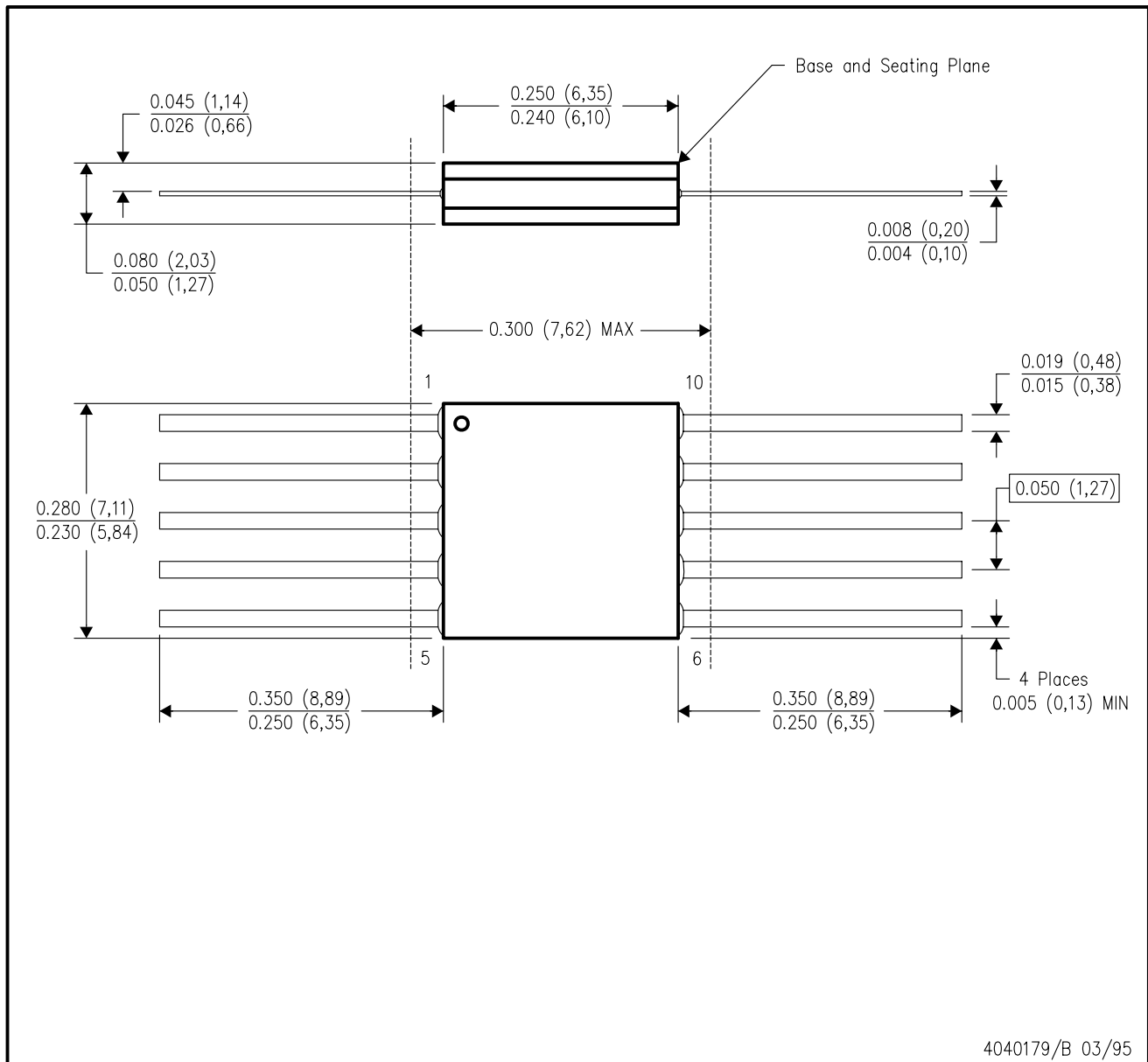


4040083/F 03/03

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package is hermetically sealed with a ceramic lid using glass frit.
 - Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

U (S-GDFP-F10)

CERAMIC DUAL FLATPACK



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a ceramic lid using glass frit.
 - Index point is provided on cap for terminal identification only.
 - Falls within MIL STD 1835 GDFP1-F10 and JEDEC MO-092AA

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a ceramic lid using glass frit.
 - Index point is provided on cap for terminal identification only.
 - Falls within MIL STD 1835 GDFP1-F14 and JEDEC MO-092AB

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a metal lid.
 - D. The terminals are gold plated.
 - E. Falls within JEDEC MS-004

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G8)

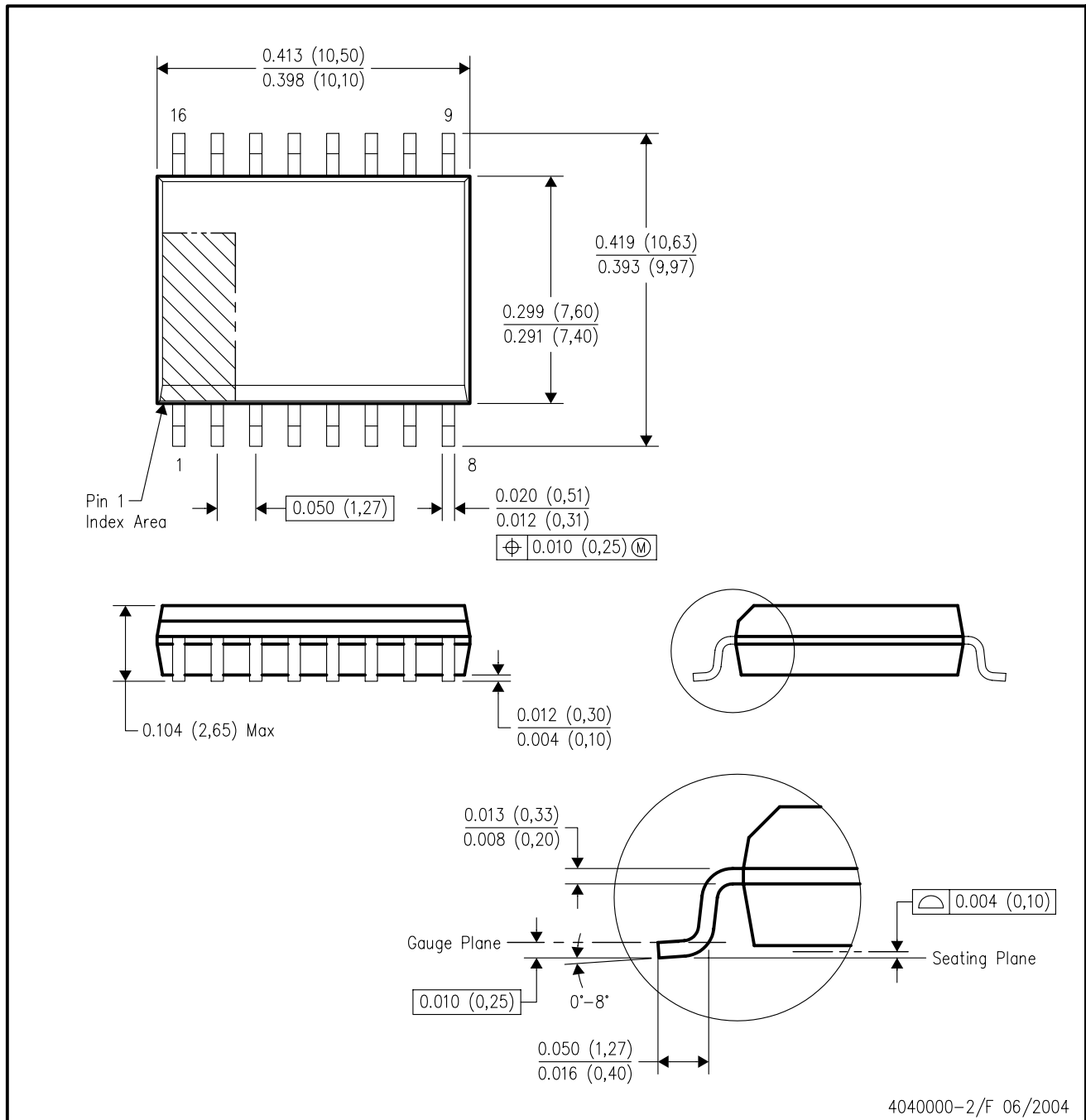
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - E. Reference JEDEC MS-012 variation AA.

DW (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AA.

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